

SILICON MMIC LOW CURRENT AMPLIFIERS FOR CELLULAR/CORDLESS TELEPHONES

DESCRIPTION

The μ PC8128TB, 8151TB and 8152TB are silicon monolithic integrated circuits designed as buffer amplifiers for cellular or cordless telephones. These amplifiers can realize low current consumption with external chip inductor (eg 1005 size) which can not be realized on internal 50 Ω wideband matched IC. These low current amplifiers operate on 3.0 V. These amplifiers packaged in super-minimold contributes to reduce your system size.

These ICs are manufactured using NEC's 20 GHz fr NESAT™ III silicon bipolar process. This process uses silicon nitride passivation film and gold electrodes. These materials can protect chip surface from external pollution and prevent corrosion/migration. Thus, these ICs have excellent performance, uniformity and reliability.

FEATURES

- Low current consumption : μ PC8128TB ; $I_{CC} = 2.8 \text{ mA}_{TYP.} @ V_{CC} = 3.0 \text{ V}$
 μ PC8151TB ; $I_{CC} = 4.2 \text{ mA}_{TYP.} @ V_{CC} = 3.0 \text{ V}$
 μ PC8152TB ; $I_{CC} = 5.6 \text{ mA}_{TYP.} @ V_{CC} = 3.0 \text{ V}$
- Supply voltage : $V_{CC} = 2.4 \text{ to } 3.3 \text{ V}$
- High efficiency : μ PC8128TB ; $P_{O(1 \text{ dB})} = -4.0 \text{ dBm}_{TYP.} @ f = 1 \text{ GHz}$
 μ PC8151TB ; $P_{O(1 \text{ dB})} = +2.5 \text{ dBm}_{TYP.} @ f = 1 \text{ GHz}$
 μ PC8152TB ; $P_{O(1 \text{ dB})} = -4.5 \text{ dBm}_{TYP.} @ f = 1 \text{ GHz}$
- Power gain variation : μ PC8128TB, 8151TB ; $G_P = 12.5 \text{ dB}_{TYP.} @ f = 1 \text{ GHz}$
 μ PC8152TB ; $G_P = 23 \text{ dB}_{TYP.} @ f = 1 \text{ GHz}$
- Operating frequency : 100 MHz to 1900 MHz (Output port LC matching)
- Excellent isolation : μ PC8128TB ; $ISL = 39 \text{ dB}_{TYP.} @ f = 1 \text{ GHz}$
 μ PC8151TB ; $ISL = 38 \text{ dB}_{TYP.} @ f = 1 \text{ GHz}$
 μ PC8152TB ; $ISL = 40 \text{ dB}_{TYP.} @ f = 1 \text{ GHz}$
- High-density surface mounting : 6-pin super minimold package (2.0 \times 1.25 \times 0.9 mm)
- Light weight : 7 mg (Standard value)

APPLICATION

- Buffer Amplifiers on 800 MHz to 1900 MHz cellular or cordless telephones

Caution: Electro-static sensitive devices.

The information in this document is subject to change without notice.

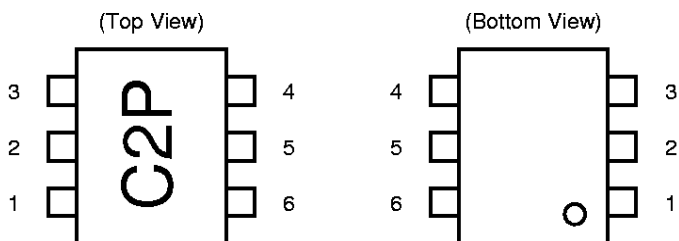
ORDERING INFORMATION

Part number	Marking	Feature	Package	Supplying form
μ PC8128TB-E3	C2P	2.8mA Low I _{CC}	6-pin super minimold	Embossed tape 8 mm wide. 1, 2, 3 pins face to perforation side of the tape. Qty 3 kp/reel.
μ PC8151TB-E3	C2U	5 mA High P _O		
μ PC8152TB-E3	C2V	5 mA High G _P		

Remarks To order evaluation samples, please contact your local NEC sales office.

(Part number for sample order: μ PC8128TB, μ PC8151TB, μ PC8152TB)

PIN CONNECTIONS



Marking is an example of μ PC8128TB

Pin NO.	Pin name
1	INPUT
2	GND
3	GND
4	OUTPUT
5	GND
6	V _{CC}

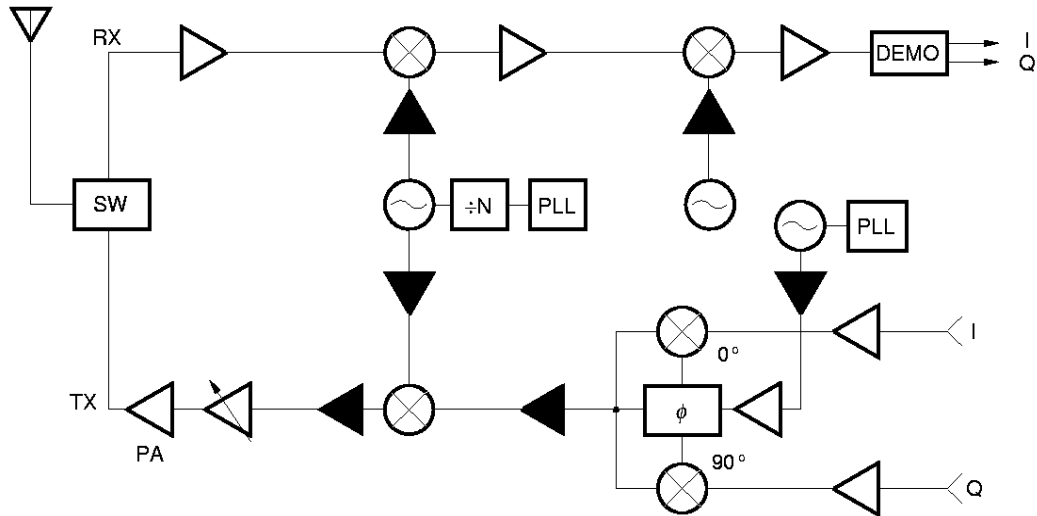
PRODUCT LINE-UP ($T_A = +25\text{ }^\circ\text{C}$, $V_{CC} = V_{out} = 3.0\text{ V}$, $Z_L = Z_S = 50\text{ }\Omega$)

Parameter Part NO.	I_{CC} (mA)	Output port matching frequency									Package	Marking
		1.0 GHz			1.66 GHz			1.9 GHz				
		G_P (dB)	ISL (dB)	$P_{O(1dB)}$ (dB)	G_P (dB)	ISL (dB)	$P_{O(1dB)}$ (dB)	G_P (dB)	ISL (dB)	$P_{O(1dB)}$ (dB)		
μ PC8128TB	2.8	12.5	39	-4.0	13	39	-4.0	13	37	-4.0	6-pin super minimold	C2P
μ PC8151TB	4.2	12.5	38	+2.5	15	36	+1.5	15	34	+0.5		C2U
μ PC8152TB	5.6	23	40	-4.5	19.5	36	-8.5	17.5	35	-8.5		C2V

Remarks Typical performance. Please refer to ELECTRICAL CHARACTERISTICS in detail.

SYSTEM APPLICATION EXAMPLE

Location examples in digital cellular



These ICs can be added to your system around \blacktriangle parts, when you need more isolation or gain. The application herein, however, shows only examples, therefore the application can depend on your kit evaluation.

PIN EXPLANATION

Pin NO.	Pin Name	Applied voltage V	Pin voltage V ^{Note}	Function and applications	Internal equivalent circuit
1	INPUT	-	0.9	Signal input pin. A internal matching circuit, configured with resistors, enables 50 Ω connection over a wide band. This pin must be coupled to signal source with capacitor for DC cut.	<p>μPC8128TB, μPC8151TB</p>
			1.06		
			0.80		
4	OUTPUT	voltage as same as V_{CC} through external inductor	-	Signal output pin. This pin is designed as collector output. Due to the high impedance output, this pin should be externally equipped with LC matching circuit to next stage. For L, a size 1005 chip in-ductor can be chosen.	<p>μPC8152TB</p>
6	V_{CC}	2.4 to 3.3	-	Power supply pin. This pin should be externally equipped with bypass capacitor to minimize its impedance.	
2 3 5	GND	0	-	Ground pin. This pin should be connected to system ground with minimum inductance. Ground pattern on the board should be formed as wide as possible. All the ground pins must be connected together with wide ground pattern to decrease impedance defference.	

Note Pin voltage is measured at $V_{CC} = 3.0$ V. Above: μ PC8128TB, Center: μ PC8151TB, Below: μ PC8152TB

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	CONDITION	RATINGS	UNIT
Supply voltage	V _{CC}	T _A = +25 °C, Pin 4, Pin 6	3.6	V
Total circuit current	I _{CC}	T _A = +25 °C	15	mA
Total power dissipation	P _D	Mounted on double sided copper clad 50 × 50 × 1.6 mm epoxy glass PWB (T _A = +85 °C)	200	mW
Operating ambient temperature	T _A		-40 to +85	°C
Storage temperature	T _{stg}		-55 to +150	°C
Input power	P _{in}	T _A = +25 °C	+5	dBm

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	NOTICE
Supply voltage	V _{CC}	2.4	3.0	3.3	V	The same voltage should be applied to pin4 and pin6.
Operating ambient temperature	T _A	-40	+25	+85	°C	
Operating frequency	f	100		1900	MHz	Matched output port with external LC

ELECTRICAL CHARACTERISTICS (Unless otherwise specified, $T_A = +25\text{ }^\circ\text{C}$, $V_{CC} = V_{out} = 3.0\text{ V}$, $Z_L = Z_s = 50\text{ }\Omega$, at LC matched frequency)

PARAMETER	SYMBOL	TEST CONDITION	μ PC8128TB			μ PC8151TB			μ PC8152TB			UNIT
			MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	
Circuit current	I_{CC}	No signal	1.8	2.8	3.8	2.8	4.2	5.8	4.2	5.6	7.1	mA
Power gain	G_P	$f = 1.00\text{ GHz}$	9.5	12.5	14.5	9.5	12.5	14.5	20	23	25	dB
		$f = 1.66\text{ GHz}$	10	13	15	12	15	17	16.5	19.5	21.5	
		$f = 1.90\text{ GHz}$	10	13	15	12	15	17	14.5	17.5	19.5	
Isolation	ISL	$f = 1.00\text{ GHz}$	34	39	–	33	38	–	35	40	–	dB
		$f = 1.66\text{ GHz}$	34	39	–	31	36	–	32	36	–	
		$f = 1.90\text{ GHz}$	32	37	–	29	34	–	30	35	–	
Gain 1 dB compression output level	$P_{O(1dB)}$	$f = 1.00\text{ GHz}$	–7.5	–4.0	–	–1.0	+2.5	–	–7.5	–4.5	–	dBm
		$f = 1.66\text{ GHz}$	–8.5	–4.0	–	–2.5	+1.5	–	–11.5	–8.5	–	
		$f = 1.90\text{ GHz}$	–8.5	–4.0	–	–3.0	+0.5	–	–11.5	–8.5	–	
Saturated output power level ^{Note} ($P_{in} = -6\text{ dBm}$)	$P_{O(sat)}$	$f = 1.00\text{ GHz}$	–	–	–	–	–	–	–2.5	+0.5	–	dB
		$f = 1.66\text{ GHz}$	–	–	–	–	–	–	–5.5	–2.5	–	
		$f = 1.90\text{ GHz}$	–	–	–	–	–	–	–7.0	–3.0	–	
Noise figure	NF	$f = 1.00\text{ GHz}$	–	6.0	7.5	–	6.0	7.5	–	3.5	5.0	dB
		$f = 1.66\text{ GHz}$	–	6.0	7.5	–	6.0	7.5	–	4.0	5.5	
		$f = 1.90\text{ GHz}$	–	6.0	7.5	–	6.0	7.5	–	4.5	6.0	
Input return loss (Without matching circuit)	RL_{in}	$f = 1.00\text{ GHz}$	2	5	–	2	5	–	8.5	11.5	–	dB
		$f = 1.66\text{ GHz}$	2	5	–	1	4	–	7.5	10.5	–	
		$f = 1.90\text{ GHz}$	2.5	5.5	–	1	4	–	8.5	11.5	–	

Note Saturated output power level is specified only in μ PC8152TB which has flat saturated region.

STANDARD CHARACTERISTICS (Unless otherwise specified, $T_A = +25\text{ }^\circ\text{C}$, $V_{CC} = V_{out} = 3.0\text{ V}$, $Z_L = Z_s = 50\text{ }\Omega$, at LC matched frequency)

PARAMETER	SYMBOL	CONDITIONS	Reference value			UNIT
			μ PC8128TB	μ PC8151TB	μ PC8152TB	
Output return loss (with external matching circuit)	RL_{out}	$f = 1.00\text{ GHz}$	10	10	15	dB
		$f = 1.66\text{ GHz}$	25	18	7.5	
		$f = 1.90\text{ GHz}$	14	12	7	
3rd order intermodulation distortion	IM_3	$f_1 = 1.000\text{ GHz}$, $f_2 = 1.001\text{ GHz}$, $P_{O(\text{each})} = -20\text{ dBm}$	–50	–62	–51	dBc
		$f_1 = 1.660\text{ GHz}$, $f_2 = 1.661\text{ GHz}$, $P_{O(\text{each})} = -20\text{ dBm}$	–46	–56	–43	
		$f_1 = 1.900\text{ GHz}$, $f_2 = 1.901\text{ GHz}$, $P_{O(\text{each})} = -20\text{ dBm}$	–46	–54	–42	

TEST CIRCUIT

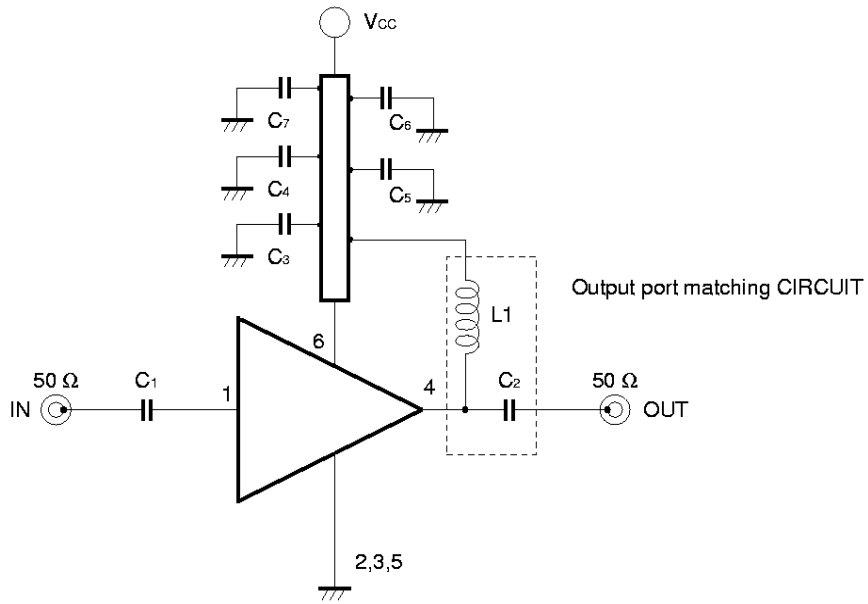
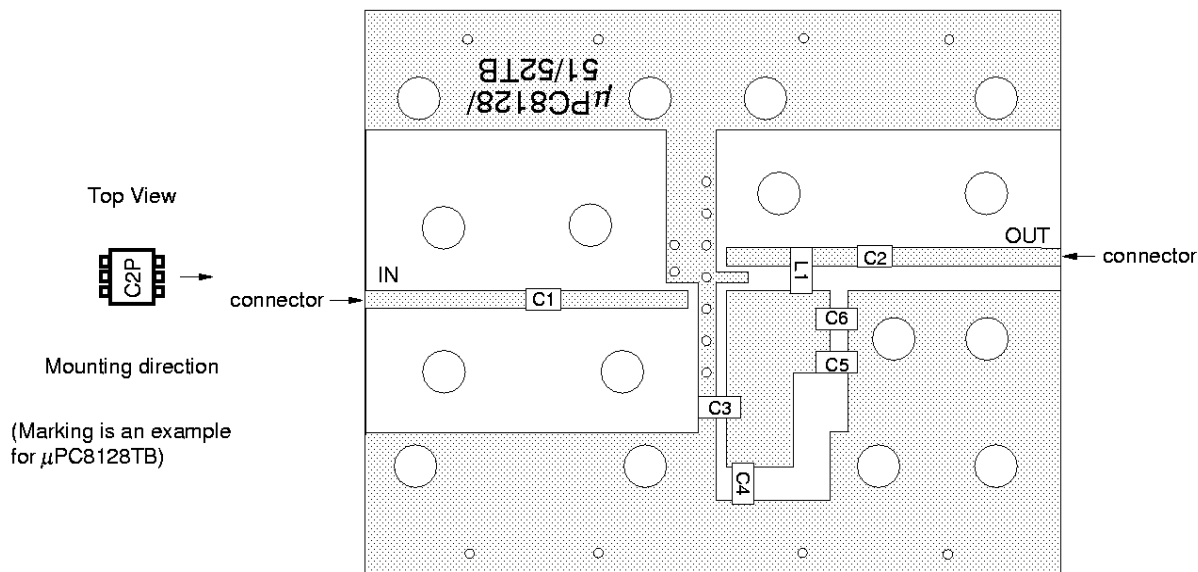


ILLUSTRATION OF THE TEST CIRCUIT ASSEMBLED ON EVALUATION BOARD

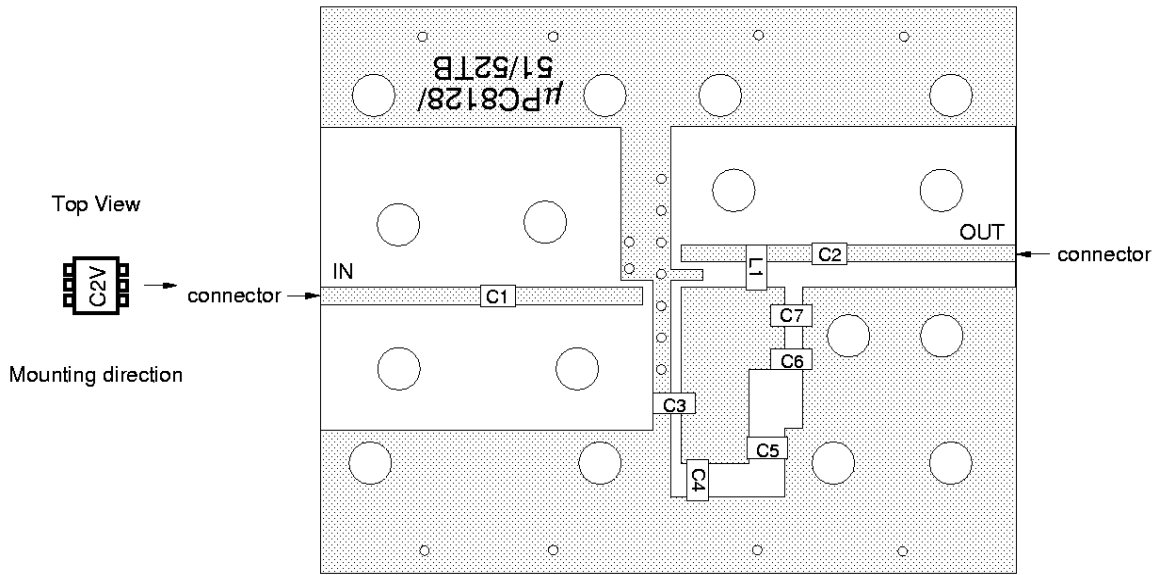
μ PC8128TB/ μ PC8151TB



COMPONENT LIST

	1.0 GHz output port matching	1.66 GHz output port matching	1.9 GHz output port matching
C1, C3 to C6	1000 pF	1000 pF	1000 pF
C2	1.0 pF	0.75 pF	0.75 pF
L1	8.2 nH	3.3 nH	2.2 nH

μ PC8152TB



COMPONENT LIST

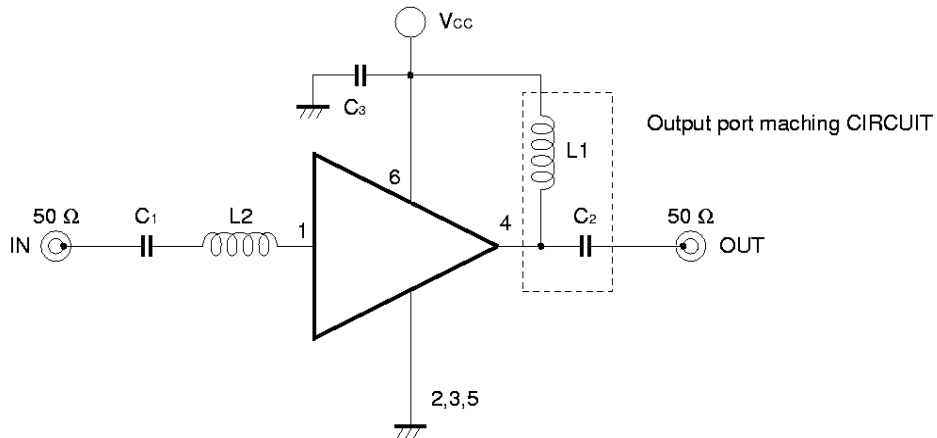
	1.0 GHz output port matching	1.66 GHz output port matching	1.9 GHz output port matching
C1, C3 to C7	1000 pF	1000 pF	1000 pF
C2	1.5 pF	1.0 pF	1.5 pF
L1	8.2 nH	1.8 nH	1.2 nH

NOTES

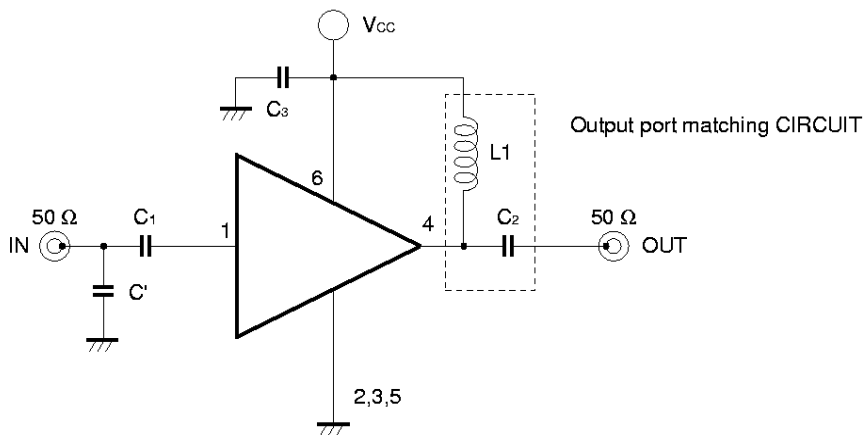
1. 42 × 35 × 0.4 mm double sided copper clad polyimide board.
2. Back side: GND pattern
3. Solder plated on pattern
4. ○ ○ ○ : Through holes

EXAMPLE OF APPLICATION CIRCUIT (μ PC8128TB, μ PC8151TB)

In improving R_{Lin} of μ PC8128TB and μ PC8151TB at 1.0 GHz, L2 should be attached.

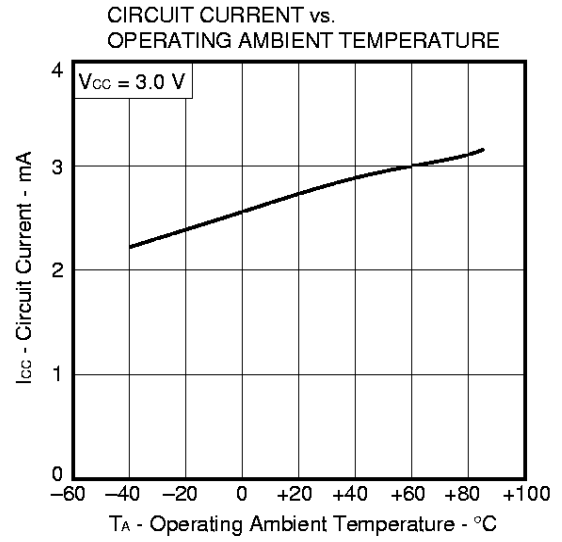
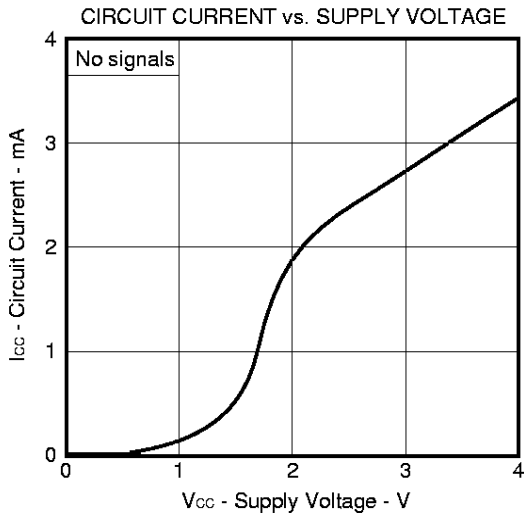


In improving R_{Lin} of μ PC8128TB and μ PC8151TB at 1.66 GHz to 1.9 GHz, C' should be attached.



TYPICAL CHARACTERISTICS (Unless otherwise specified, $T_A = +25^\circ\text{C}$)

— μ PC8128TB —

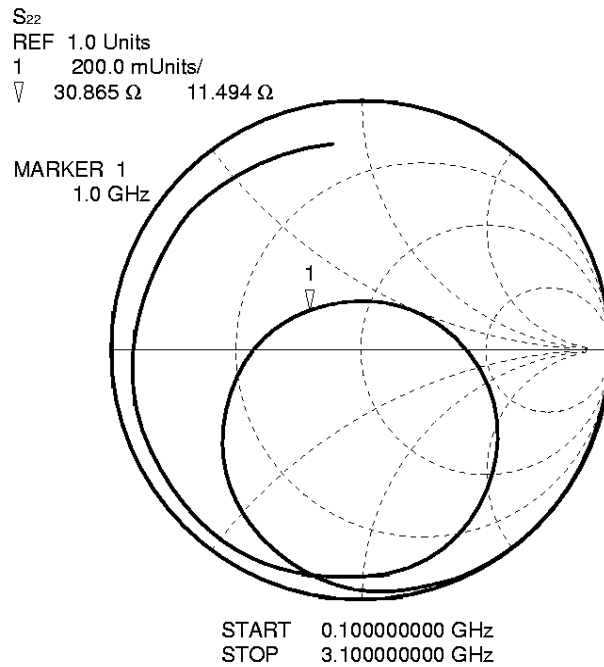
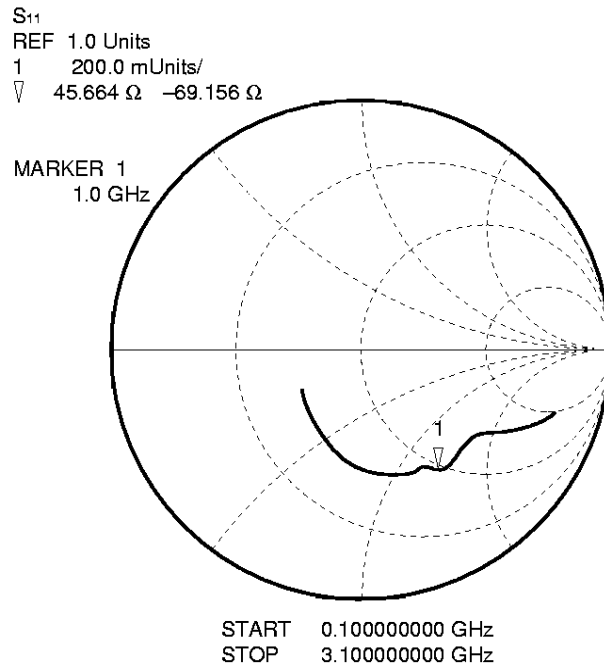


- μ PC8128TB -

1.0 GHz output port matching

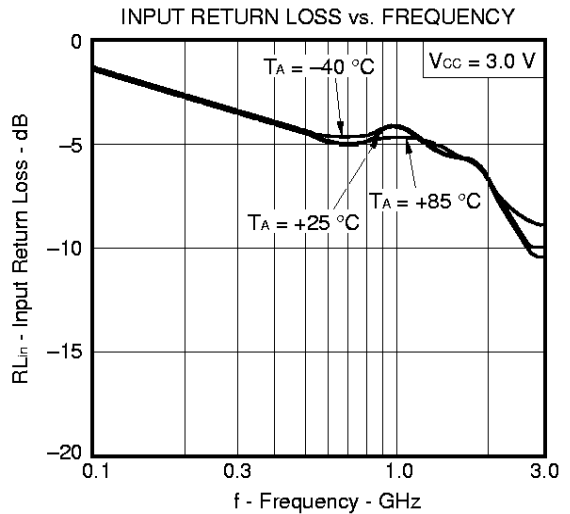
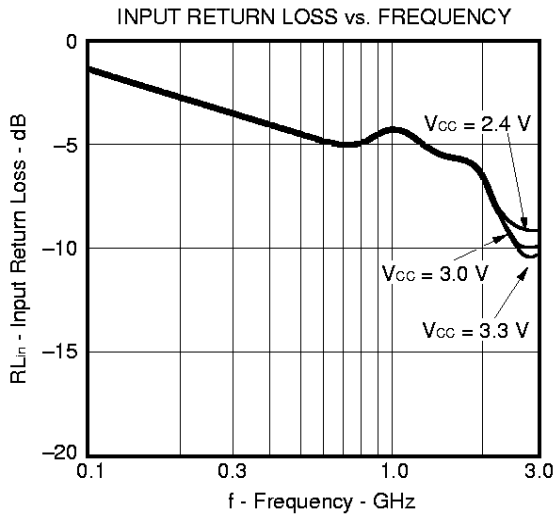
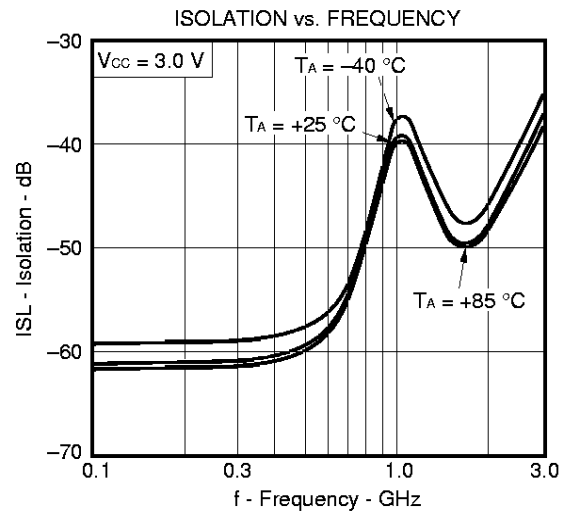
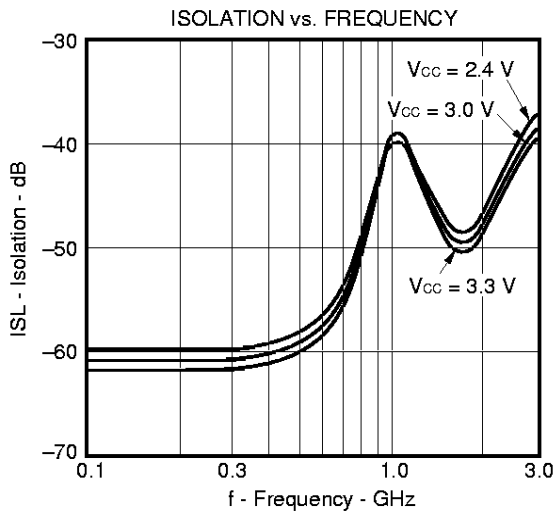
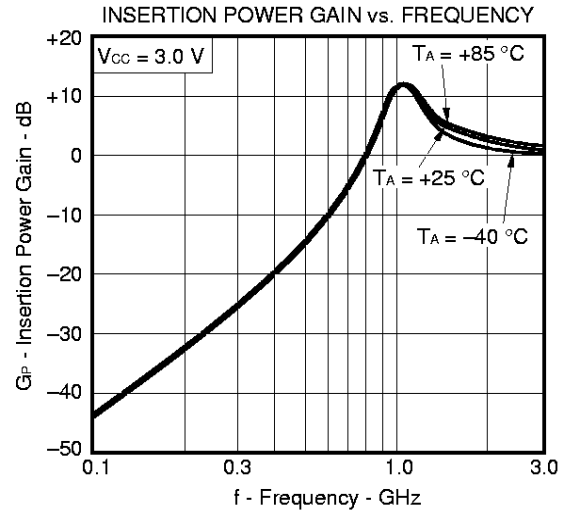
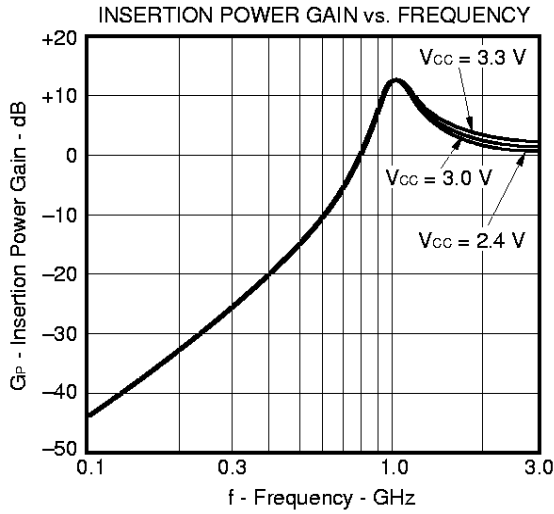
S-parameter (monitored at connector on board)

$T_A = +25^\circ\text{C}$, $V_C = V_{out} = 3.0\text{ V}$



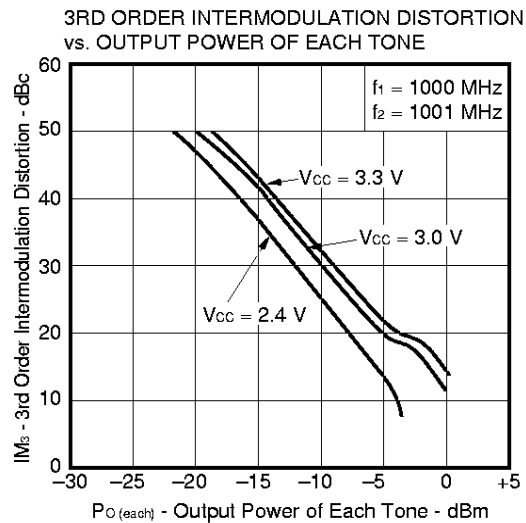
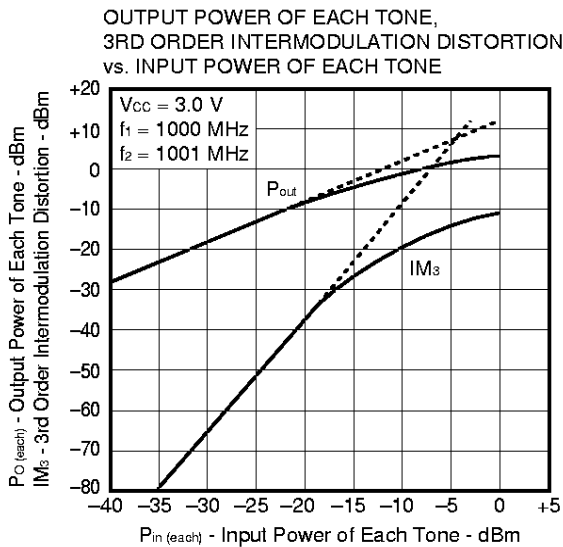
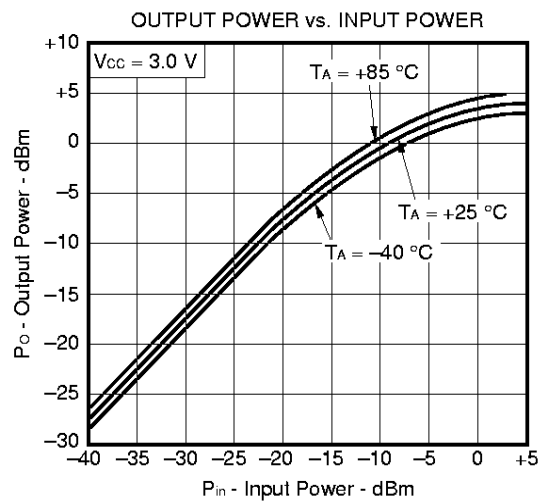
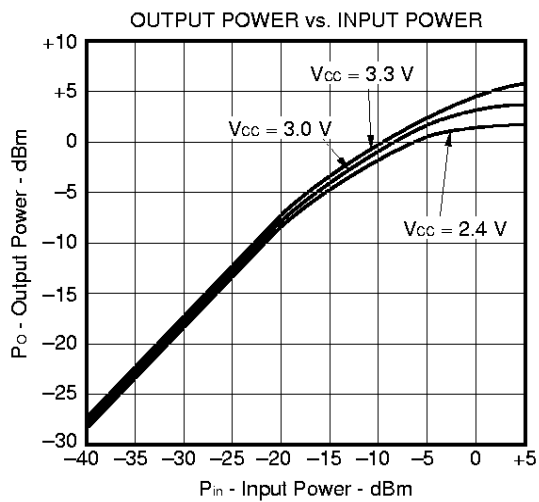
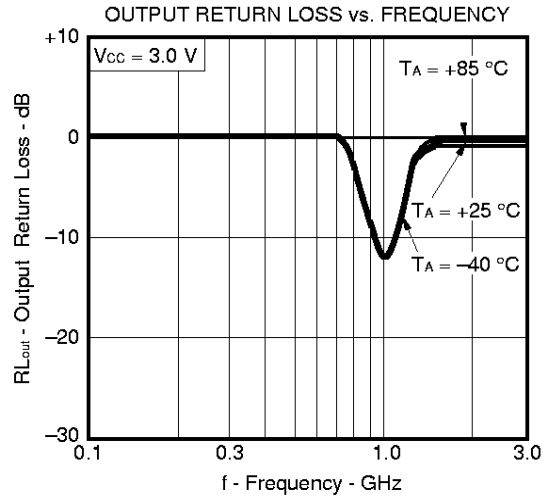
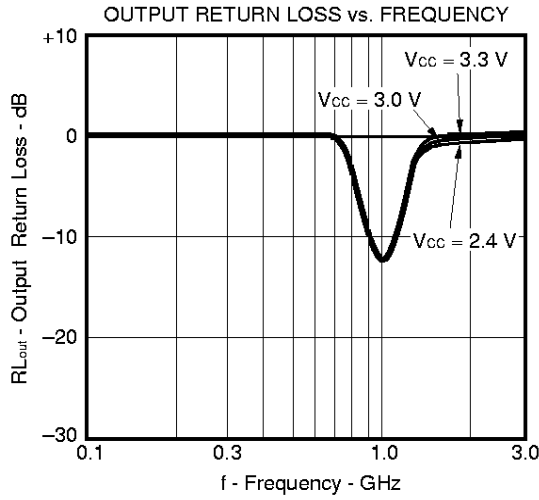
– μ PC8128TB –

1.0 GHz output port matching



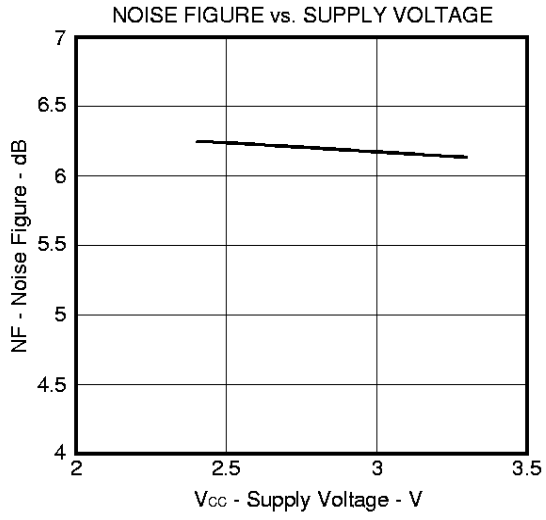
- μ PC8128TB -

1.0 GHz output port matching



– μ PC8128TB –

1.0 GHz output port matching



– μ PC8128TB –

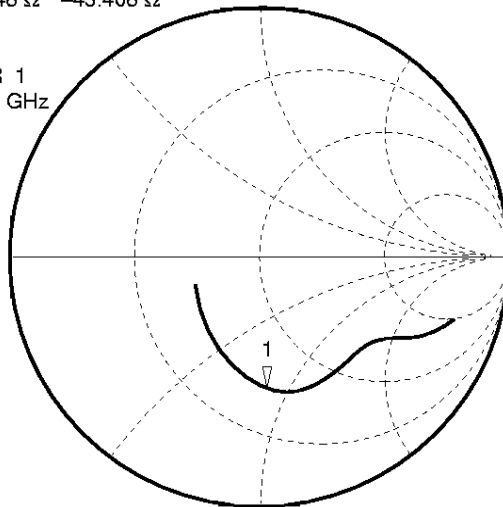
1.66 GHz output port matching

S-parameter (monitored at connector on board)

$T_A = +25^\circ\text{C}$, $V_C = V_{out} = 3.0\text{ V}$

S₁₁
 REF 1.0 Units
 1 200.0 mUnits/
 ▽ 27.846 Ω -43.406 Ω

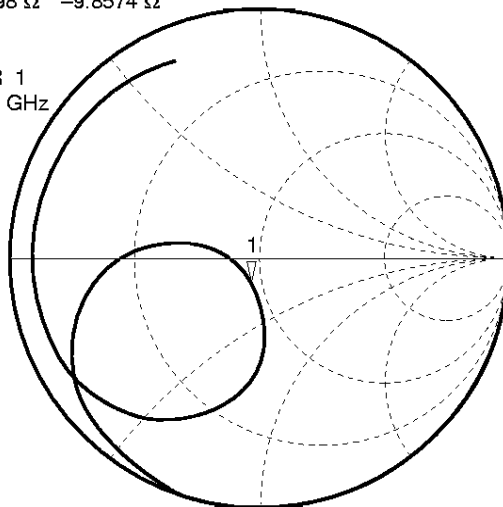
MARKER 1
 1.66 GHz



START 0.10000000 GHz
 STOP 3.10000000 GHz

S₂₂
 REF 1.0 Units
 1 200.0 mUnits/
 ▽ 46.598 Ω -9.8574 Ω

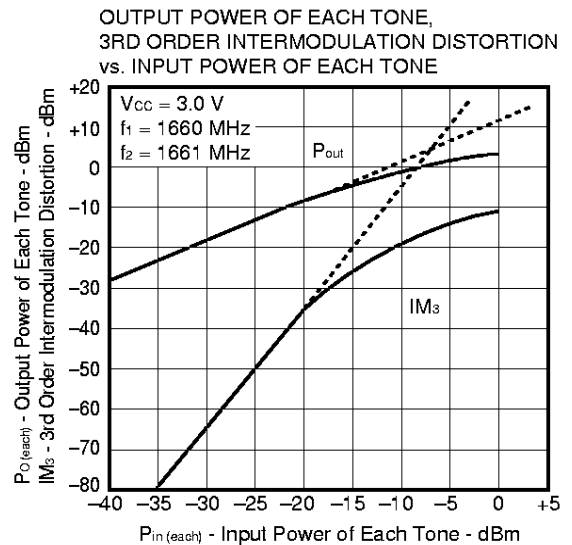
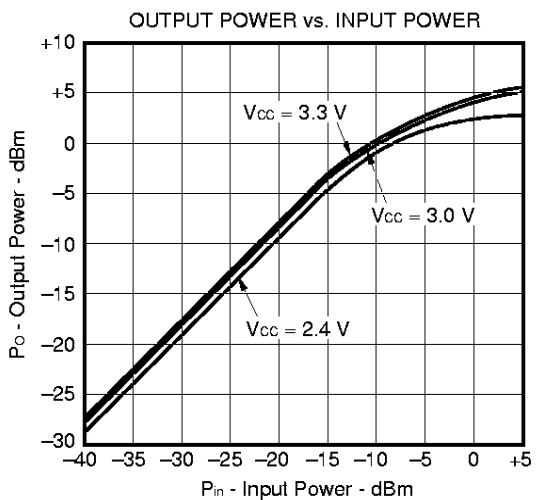
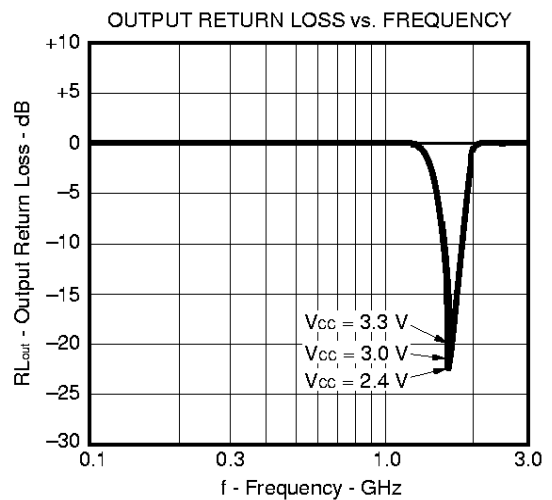
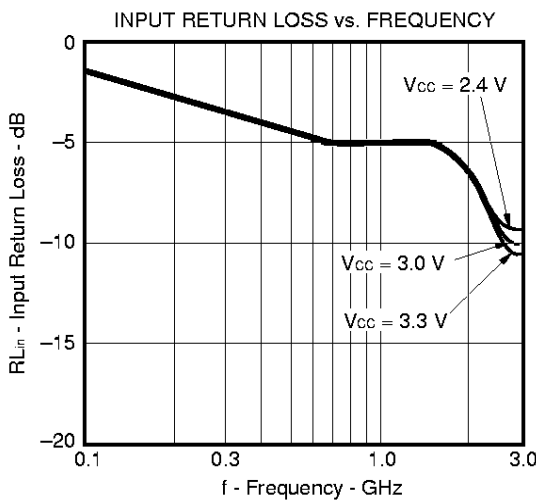
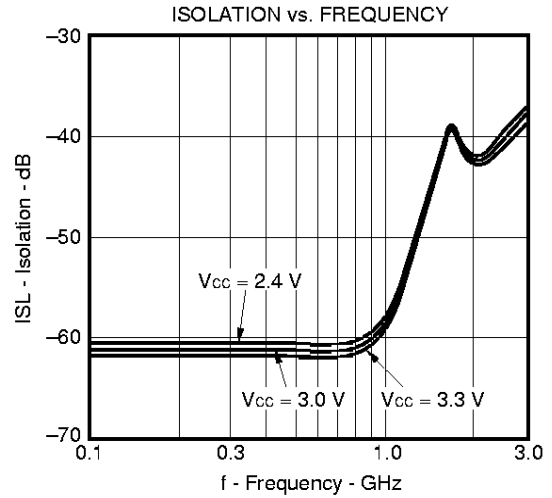
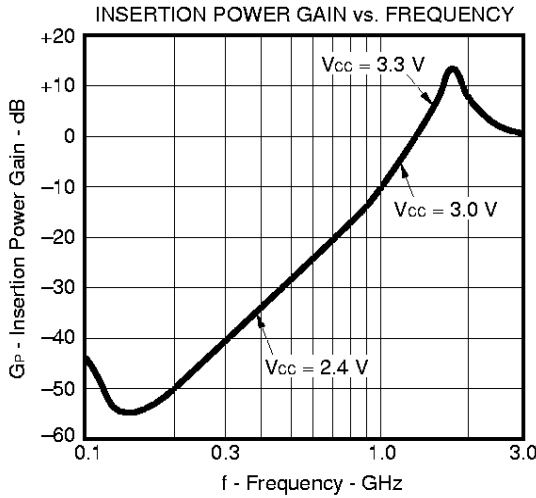
MARKER 1
 1.66 GHz



START 0.10000000 GHz
 STOP 3.10000000 GHz

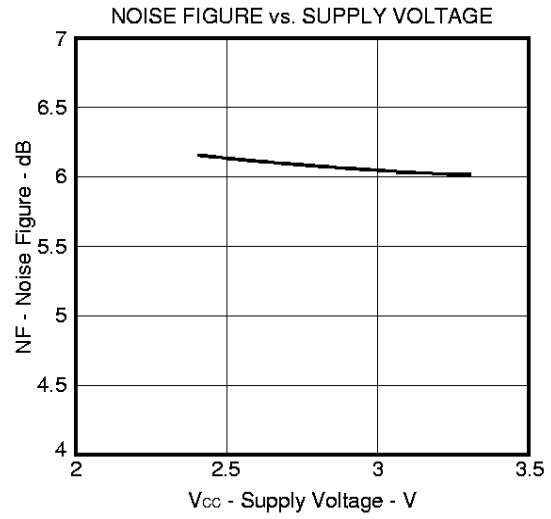
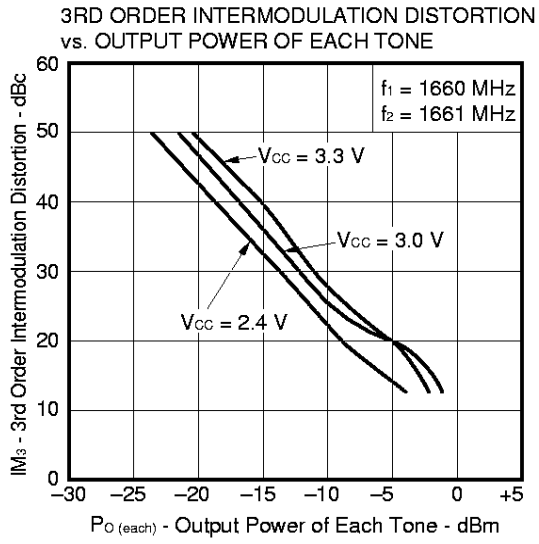
- μ PC8128TB -

1.66 GHz output port matching



– μ PC8128TB –

1.66 GHz output port matching



– μ PC8128TB –

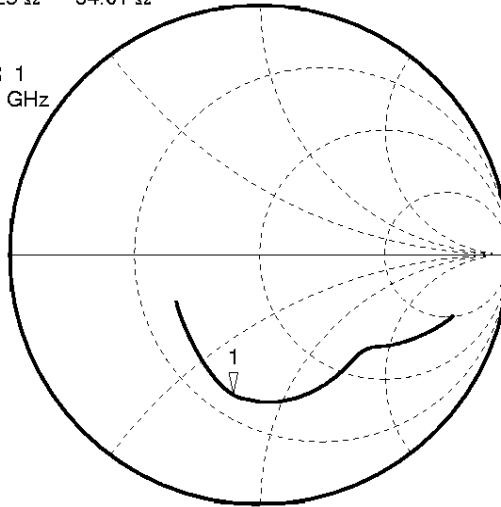
1.9 GHz output port matching

S-parameter (monitored at connector on board)

$T_A = +25^\circ\text{C}$, $V_{CC} = V_{out} = 3.0\text{ V}$

S₁₁
REF 1.0 Units
1 200.0 mUnits/
∇ 24.725 Ω -34.01 Ω

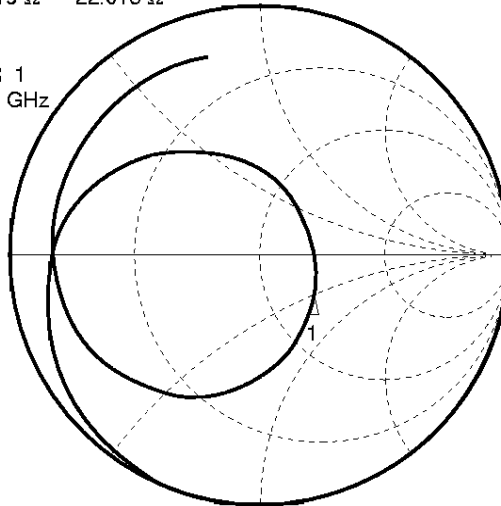
MARKER 1
1.9 GHz



START 0.100000000 GHz
STOP 3.100000000 GHz

S₂₂
REF 1.0 Units
1 200.0 mUnits/
∇ 74.719 Ω -22.016 Ω

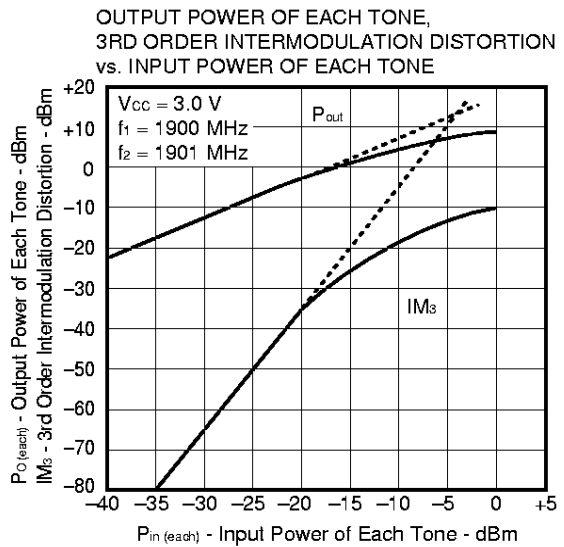
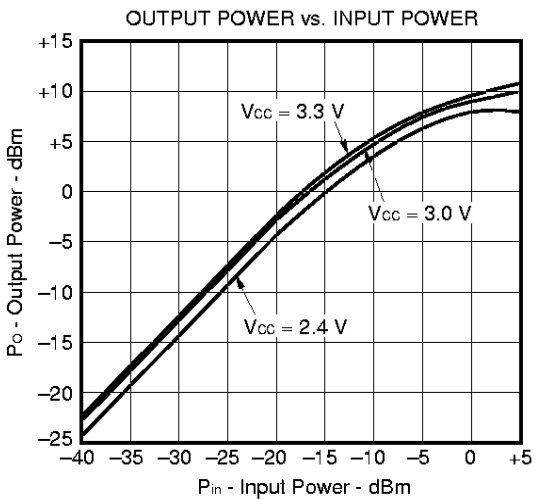
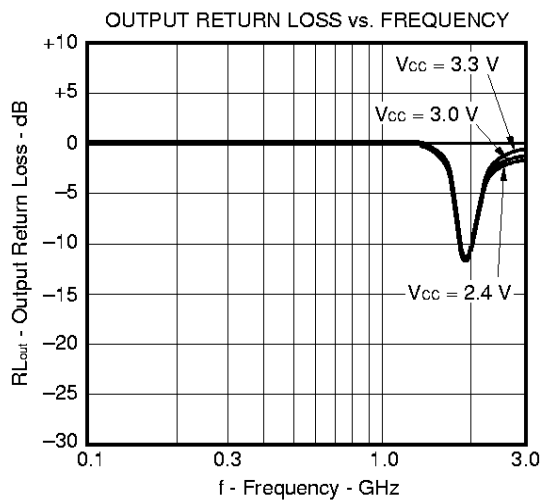
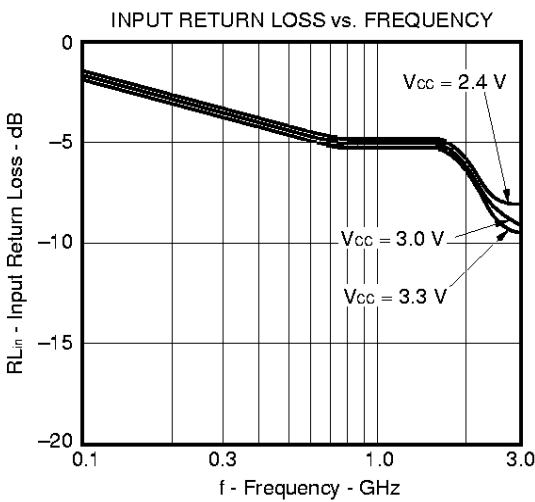
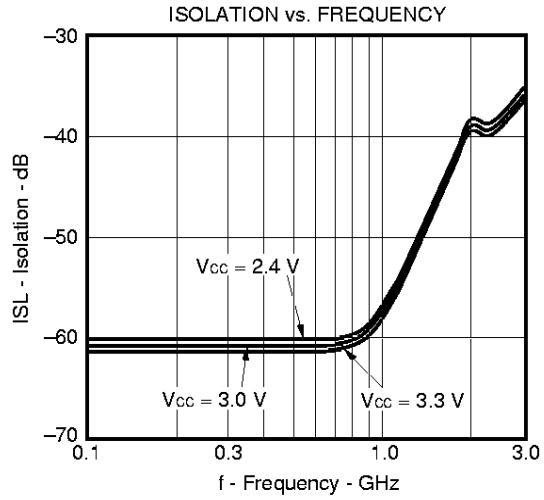
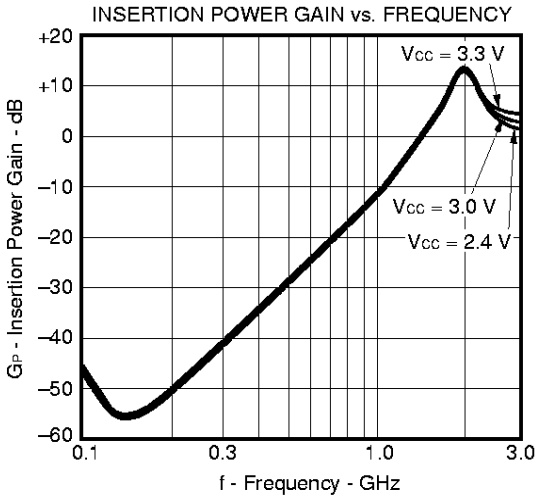
MARKER 1
1.9 GHz



START 0.100000000 GHz
STOP 3.100000000 GHz

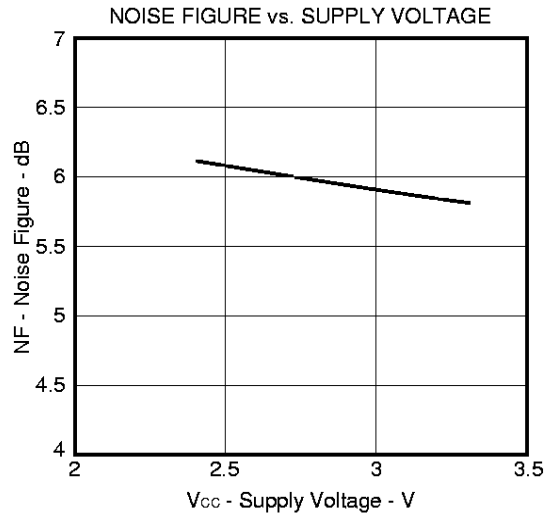
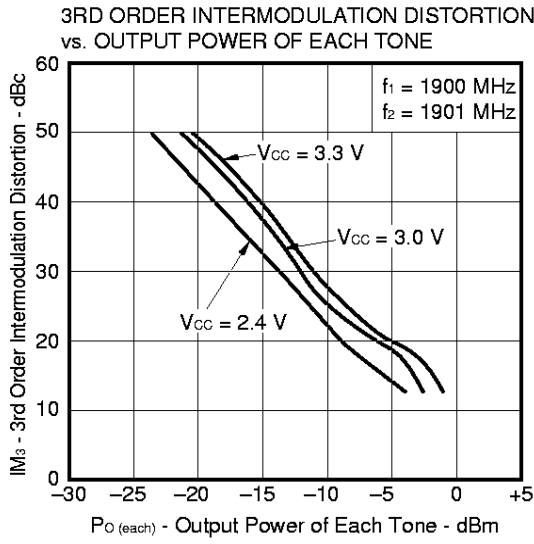
- μ PC8128TB -

1.9 GHz output port matching



- μ PC8128TB -

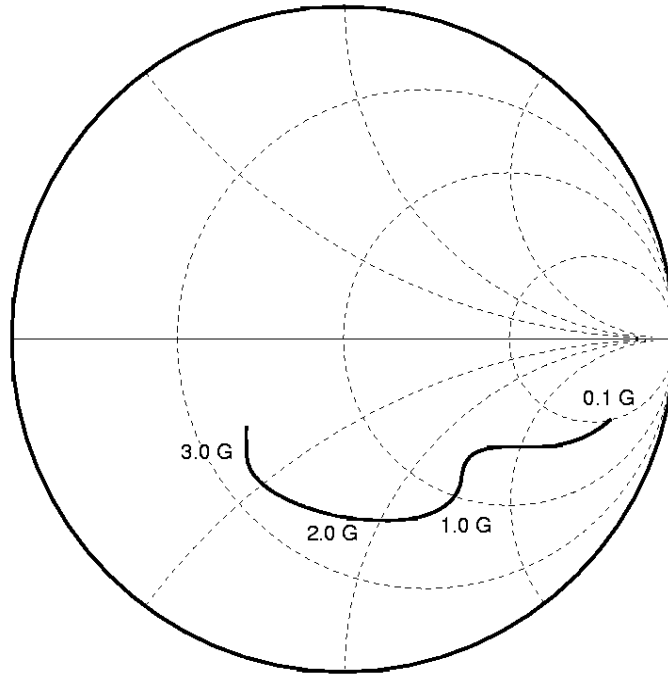
1.9 GHz output port matching



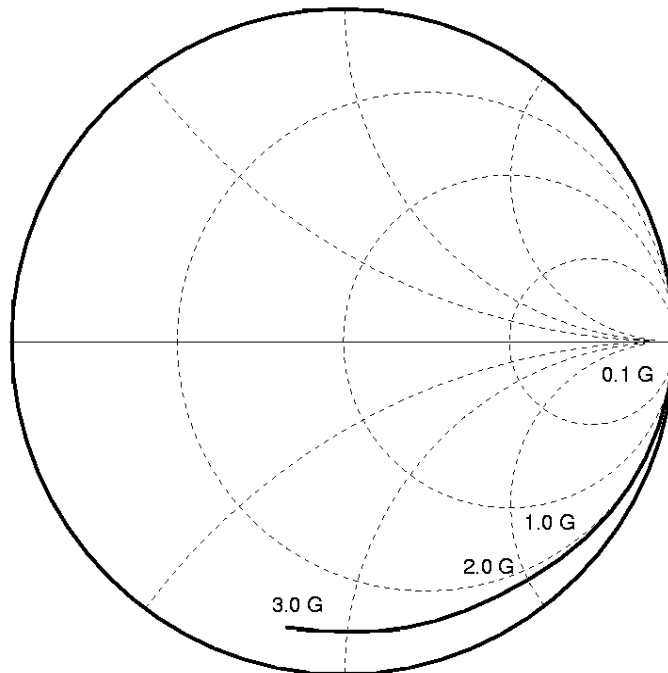
S-parameter ($V_{CC} = V_{out} = 3.0\text{ V}$)

– μ PC8128TB –

S_{11} –Frequency



S_{22} –Frequency



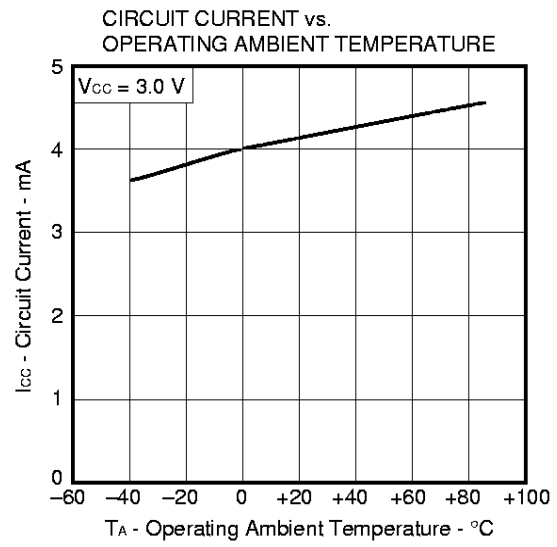
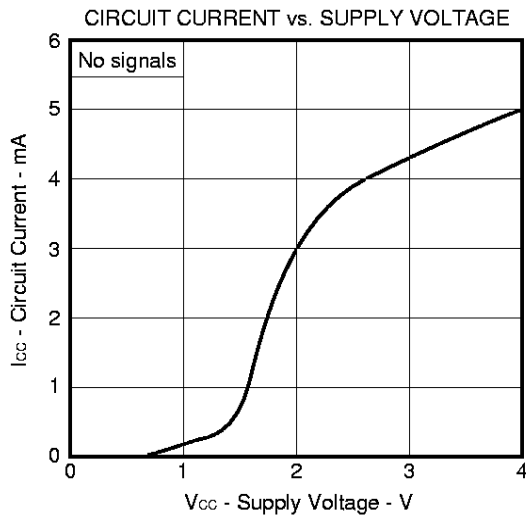
Typical S-parameter values (T_A = +25°C)

μPC8128TB

V_{CC} = V_{OUT} = 3.0 V, I_{CC} = 2.8 mA

FREQUENCY MHz	S ₁₁		S ₂₁		S ₁₂		S ₂₂	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100.0000	.859	-14.5	1.089	-176.0	.001	176.7	1.005	-1.7
200.0000	.769	-23.8	1.138	-173.2	.001	142.6	1.019	-4.2
300.0000	.694	-27.1	1.208	-171.0	.003	112.3	1.015	-5.8
400.0000	.637	-30.1	1.336	-171.7	.005	88.8	.996	-8.7
500.0000	.595	-32.4	1.478	-172.8	.005	77.7	.976	-10.9
600.0000	.568	-35.9	1.623	-175.6	.005	64.1	.976	-12.8
700.0000	.555	-40.7	1.822	-179.0	.006	73.7	.983	-14.1
800.0000	.569	-45.0	1.955	176.9	.007	64.2	.988	-15.5
900.0000	.597	-49.4	2.147	172.5	.007	72.5	.973	-17.4
1000.0000	.633	-52.6	2.307	166.8	.008	49.9	.945	-19.9
1100.0000	.643	-56.3	2.468	160.6	.008	66.8	.928	-22.0
1200.0000	.644	-59.7	2.572	153.6	.007	48.8	.934	-24.1
1300.0000	.611	-64.3	2.677	144.2	.007	45.3	.950	-24.8
1400.0000	.585	-69.5	2.704	137.3	.005	64.5	.938	-26.6
1500.0000	.562	-75.1	2.693	128.8	.005	66.0	.913	-28.2
1600.0000	.559	-80.5	2.712	122.7	.005	93.6	.898	-30.1
1700.0000	.547	-85.4	2.640	116.3	.006	83.5	.892	-32.0
1800.0000	.540	-89.5	2.665	110.4	.005	101.6	.893	-33.6
1900.0000	.524	-93.2	2.599	104.5	.005	115.4	.896	-34.7
2000.0000	.503	-97.8	2.582	98.5	.006	110.9	.895	-36.5
2100.0000	.474	-103.5	2.500	93.1	.007	129.4	.877	-38.6
2200.0000	.461	-110.0	2.472	86.7	.008	130.5	.873	-40.4
2300.0000	.465	-116.2	2.453	80.9	.009	137.8	.878	-41.9
2400.0000	.475	-121.0	2.426	74.8	.010	133.3	.877	-43.5
2500.0000	.488	-123.1	2.364	70.4	.012	139.0	.871	-45.4
2600.0000	.491	-125.0	2.310	63.9	.011	140.8	.864	-47.9
2700.0000	.480	-125.1	2.282	61.1	.014	142.6	.855	-51.1
2800.0000	.460	-127.0	2.159	56.3	.014	140.7	.851	-53.0
2900.0000	.437	-129.4	2.205	51.4	.016	141.5	.867	-55.1
3000.0000	.410	-133.4	2.085	48.8	.018	143.2	.861	-57.0
3100.0000	.401	-137.8	2.038	42.4	.019	142.1	.855	-60.0

– μ PC8151TB –



- μ PC8151TB -

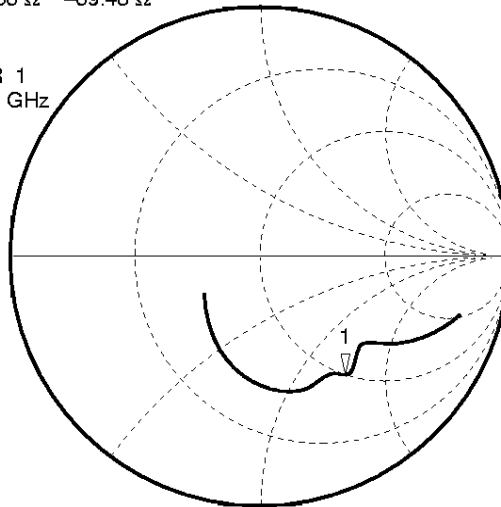
1.0 GHz output port matching

S-parameter (monitored at connector on board)

$T_A = +25^\circ\text{C}$, $V_{CC} = V_{out} = 3.0\text{ V}$

S₁₁
REF 1.0 Units
1 200.0 mUnits/
▽ 52.156 Ω -69.48 Ω

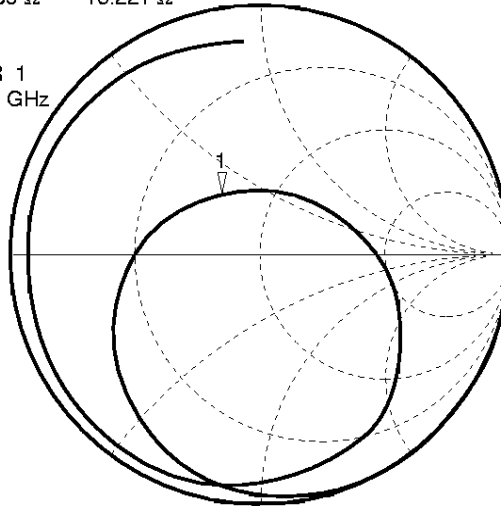
MARKER 1
1.0 GHz



START 0.10000000 GHz
STOP 3.10000000 GHz

S₂₂
REF 1.0 Units
1 200.0 mUnits/
▽ 32.893 Ω 16.221 Ω

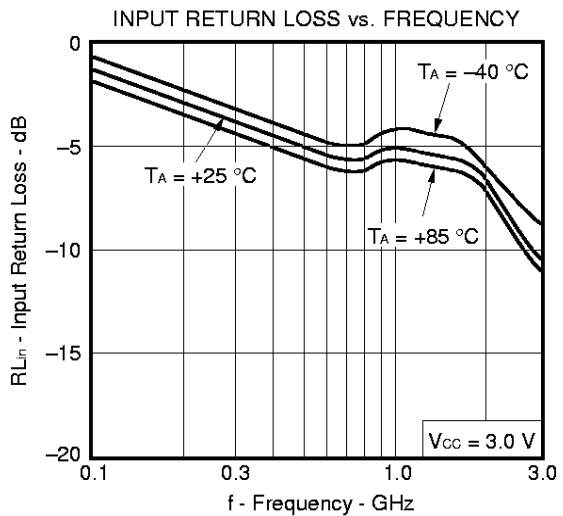
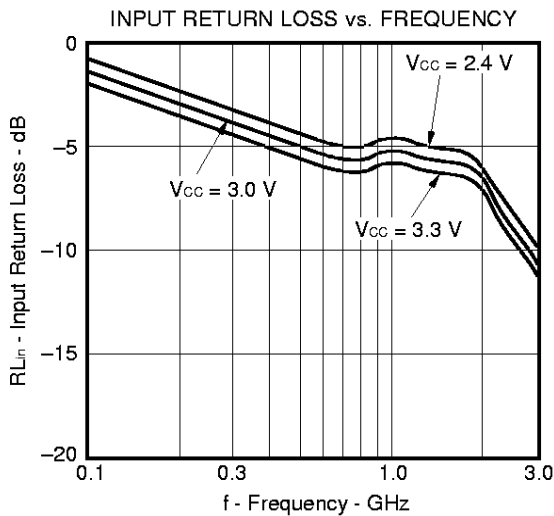
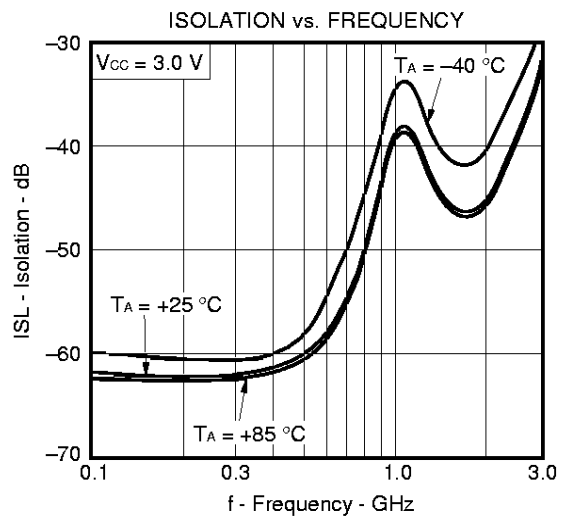
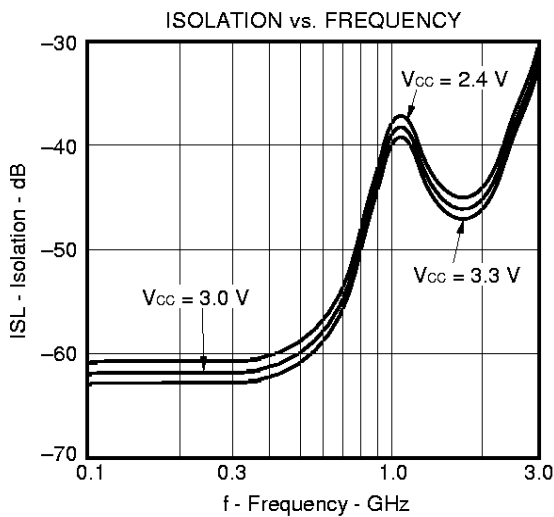
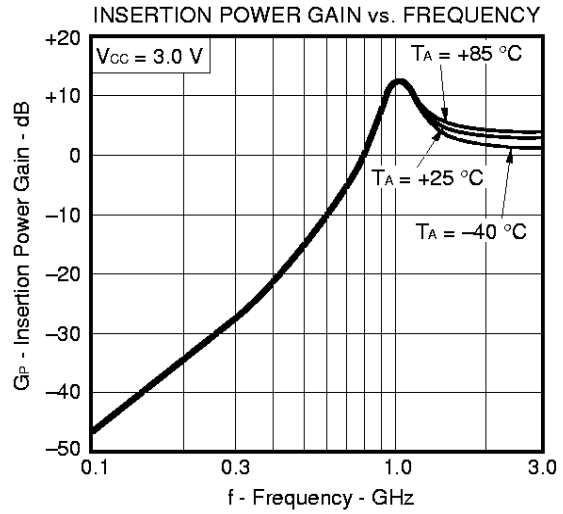
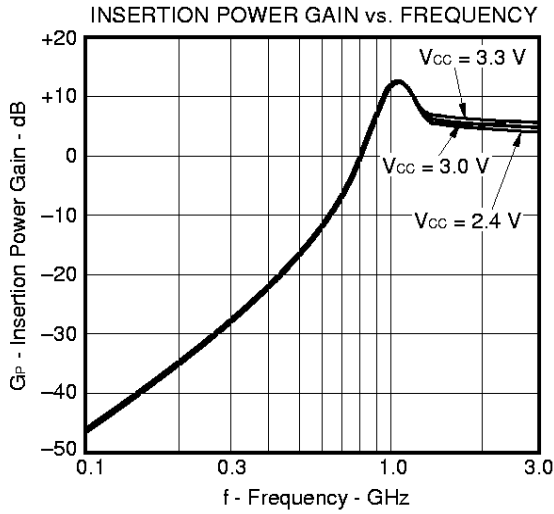
MARKER 1
1.0 GHz



START 0.10000000 GHz
STOP 3.10000000 GHz

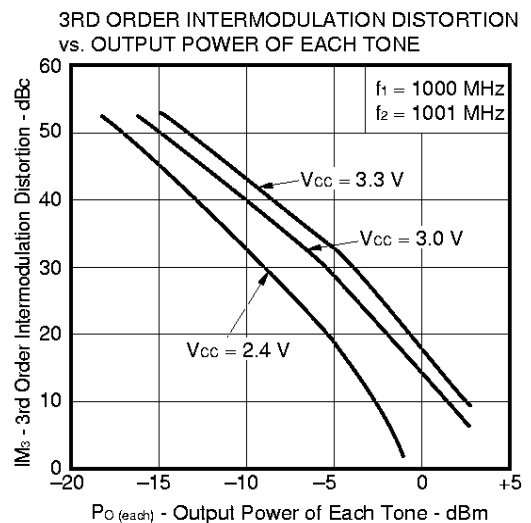
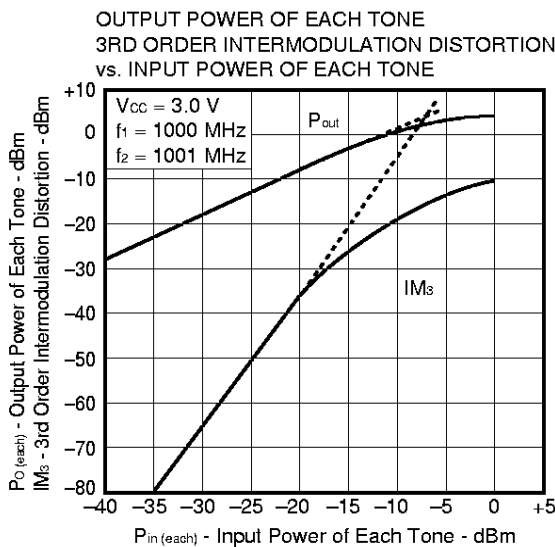
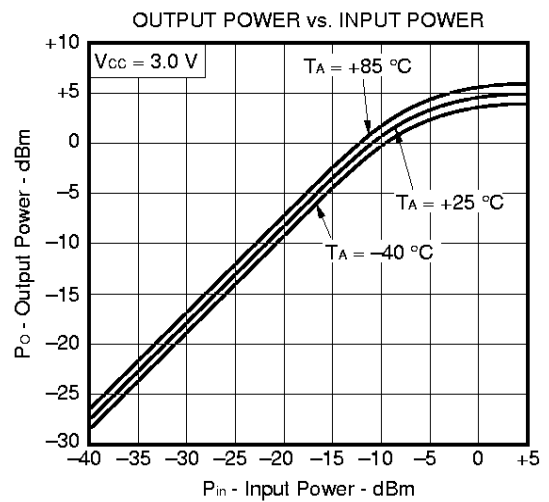
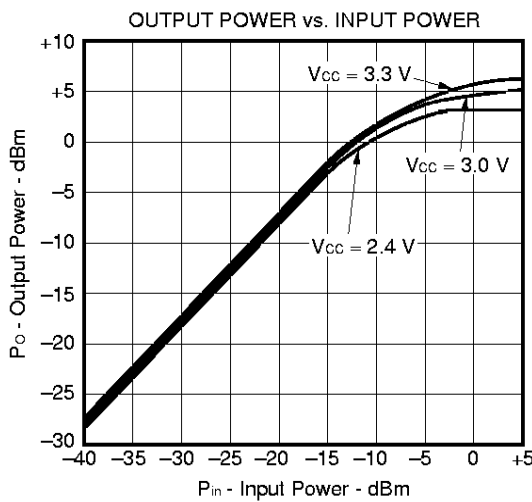
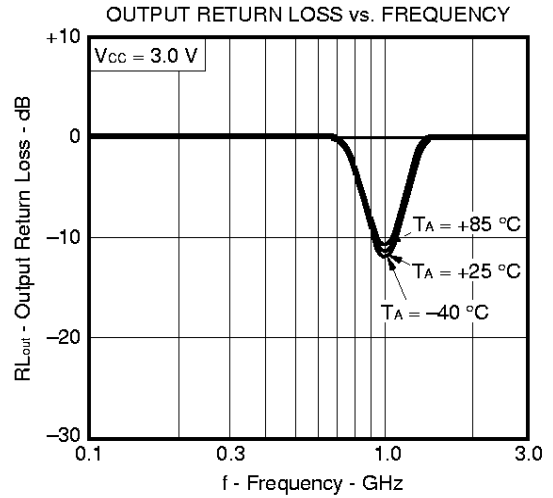
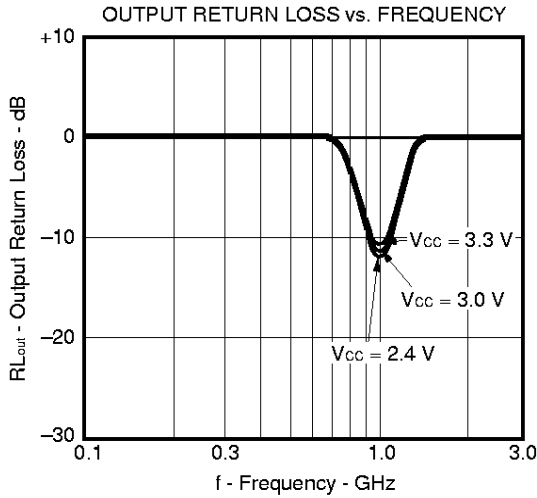
- μ PC8151TB -

1.0 GHz output port matching



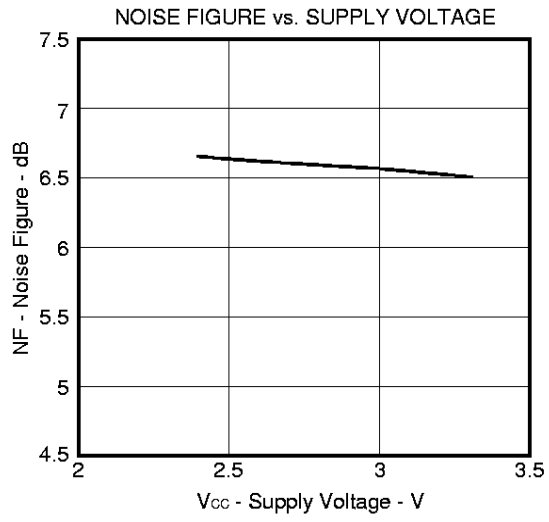
- μ PC8151TB -

1.0 GHz output port matching



– μ PC8151TB –

1.0 GHz output port matching



– μ PC8151TB –

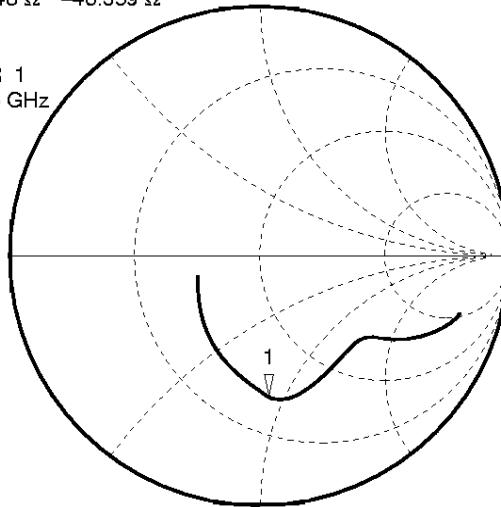
1.66 GHz output port matching

S-parameter (monitored at connector on board)

$T_A = +25^\circ\text{C}$, $V_{CC} = V_{out} = 3.0\text{ V}$

S₁₁
 REF 1.0 Units
 1 200.0 mUnits/
 ▽ 26.748 Ω -46.359 Ω

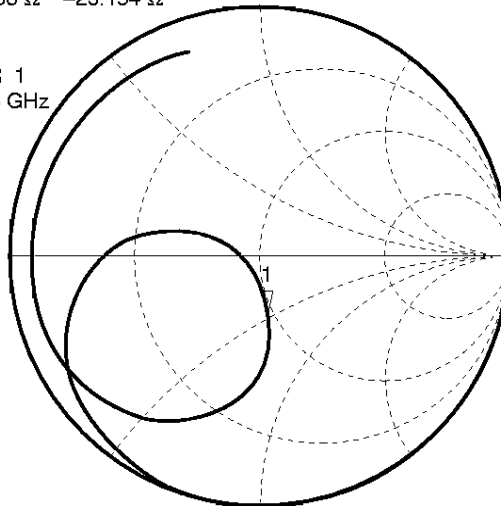
MARKER 1
 1.66 GHz



START 0.100000000 GHz
 STOP 3.100000000 GHz

S₂₂
 REF 1.0 Units
 1 200.0 mUnits/
 ▽ 49.086 Ω -23.154 Ω

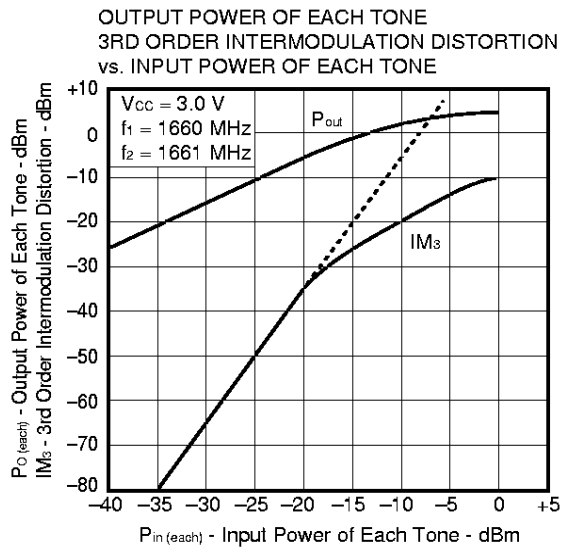
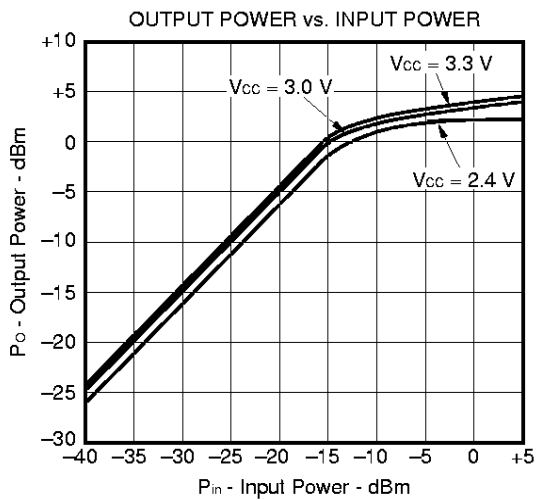
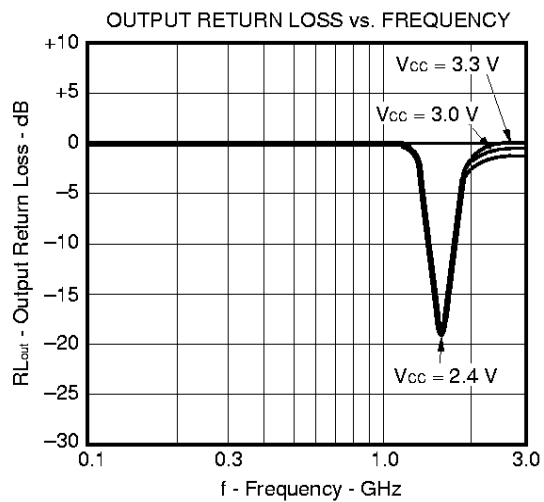
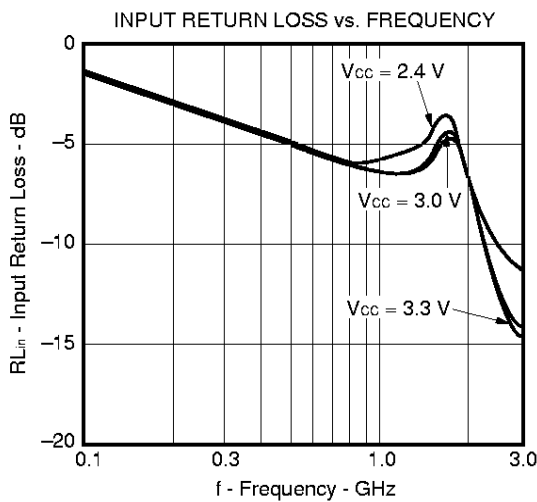
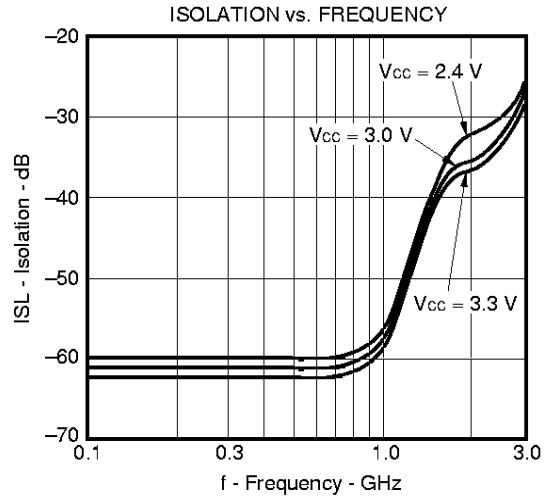
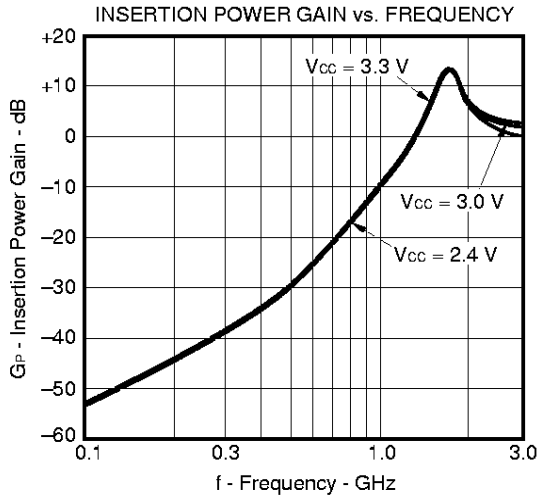
MARKER 1
 1.66 GHz



START 0.100000000 GHz
 STOP 3.100000000 GHz

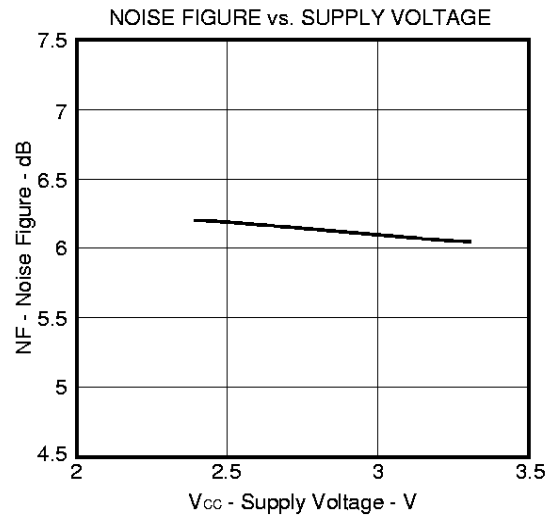
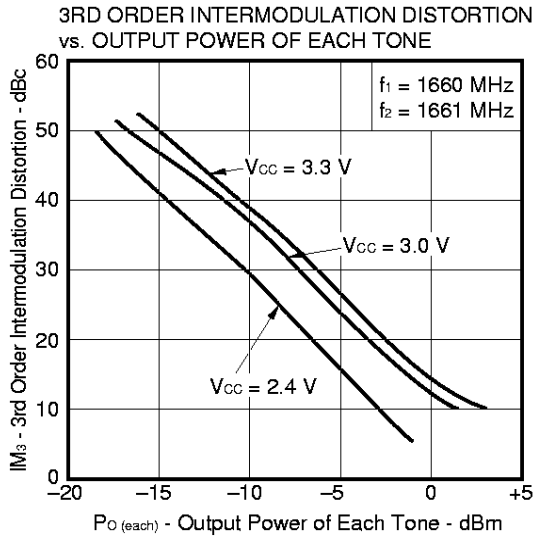
- μ PC8151TB -

1.66 GHz output port matching



- μ PC8151TB -

1.66 GHz output port matching



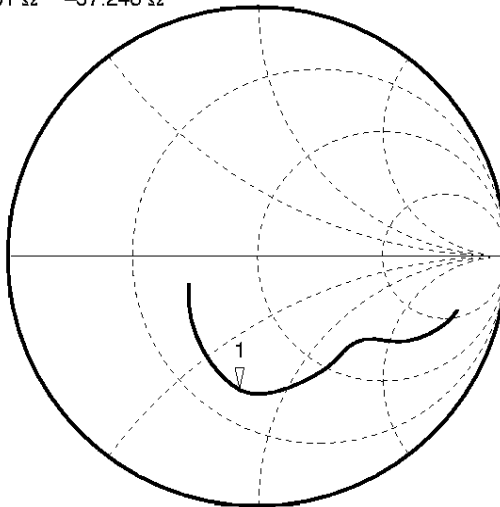
– μ PC8151TB –

1.9 GHz output port matching

S-parameter (monitored at connector on board)

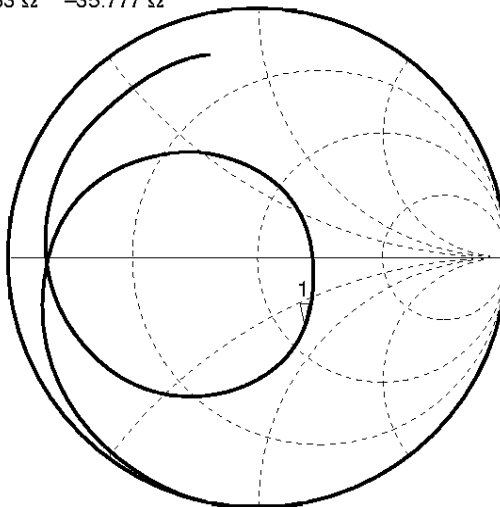
$T_A = +25^\circ\text{C}$, $V_C = V_{out} = 3.0\text{ V}$

S₁₁
 REF 1.0 Units
 1 200.0 mUnits/
 ▽ 24.301 Ω -37.246 Ω



START 0.10000000 GHz
 STOP 3.10000000 GHz

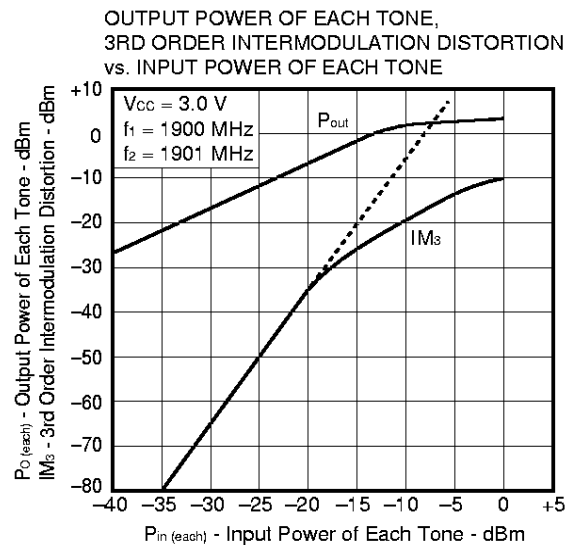
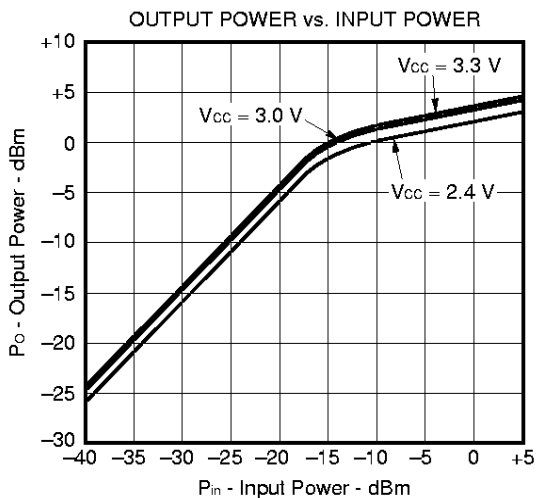
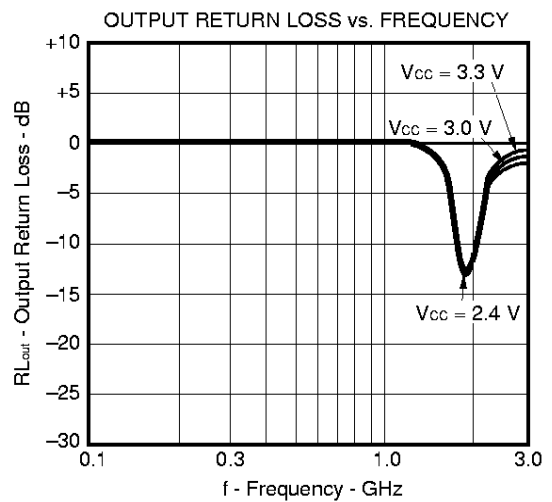
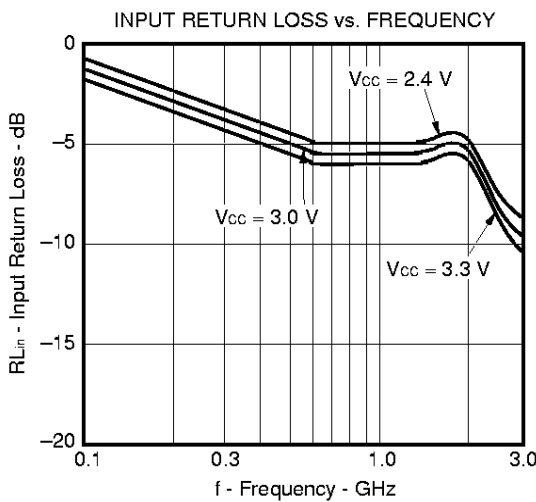
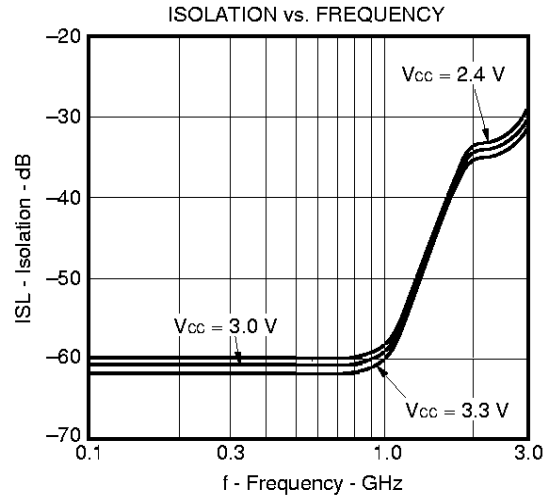
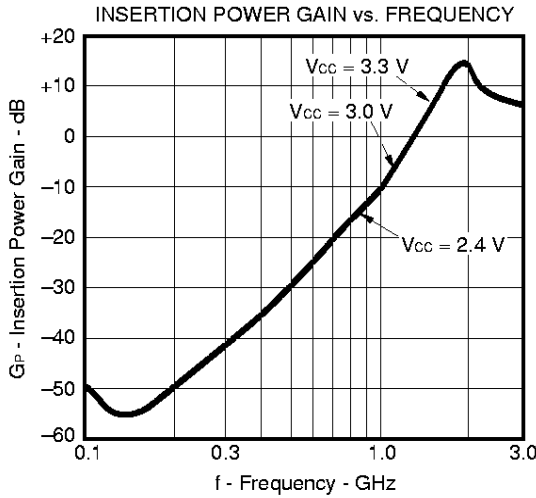
S₂₂
 REF 1.0 Units
 1 200.0 mUnits/
 ▽ 64.633 Ω -35.777 Ω



START 0.10000000 GHz
 STOP 3.10000000 GHz

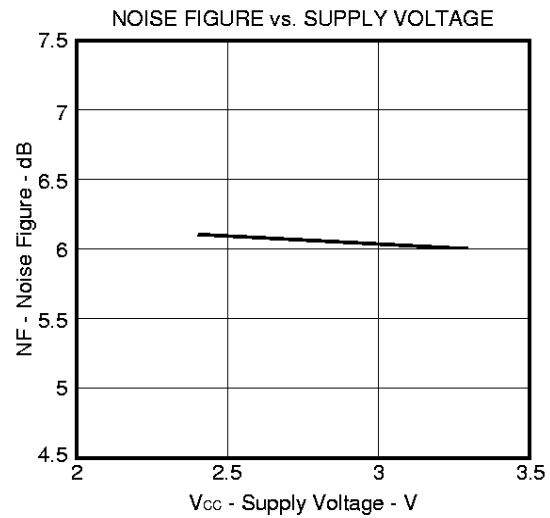
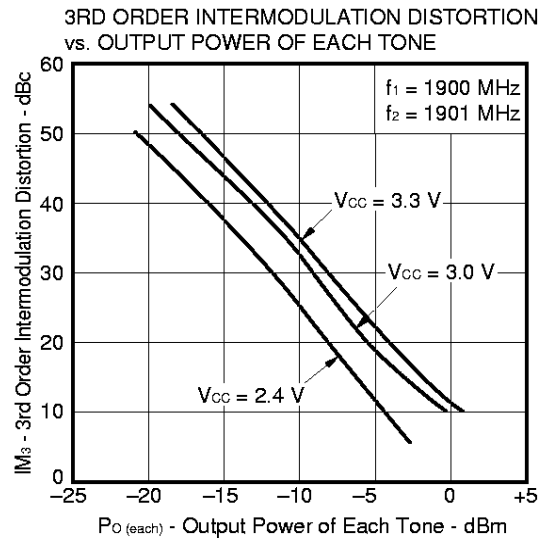
- μ PC8151TB -

1.9 GHz output port matching



– μ PC8151TB –

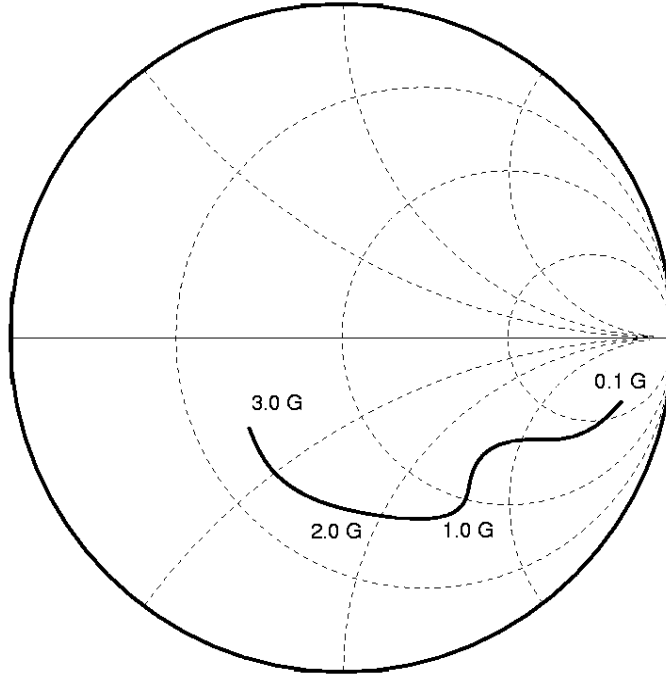
1.9 GHz output port matching



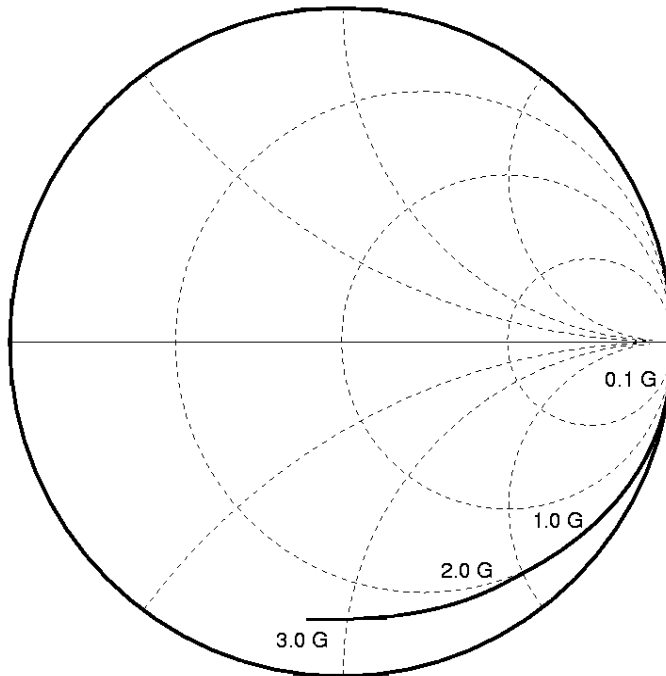
S-parameter ($V_{CC} = V_{out} = 3.0\text{ V}$)

– μ PC8151TB–

S₁₁–Frequency



S₂₂–Frequency



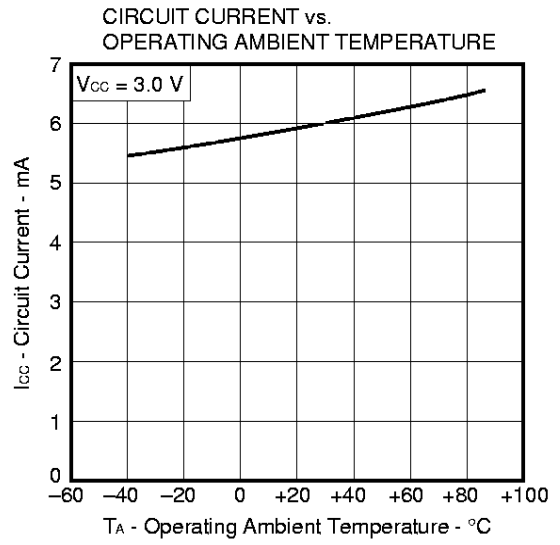
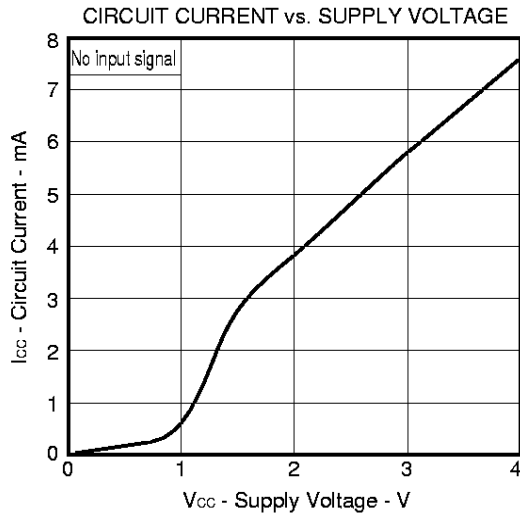
Typical S-parameter values (T_A = +25°C)

μ PC8151TB

V_{CC} = V_{out} = 3.0 V, I_{CC} = 4.2 mA

FREQUENCY MHz	S ₁₁		S ₂₁		S ₁₂		S ₂₂	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100.0000	.843	-16.0	1.202	-178.9	.000	69.5	.996	-3.3
200.0000	.752	-27.1	1.197	-177.5	.003	120.2	1.009	-6.9
300.0000	.666	-32.4	1.221	-175.4	.003	103.2	.998	-9.9
400.0000	.603	-36.8	1.299	-174.5	.004	92.8	.986	-13.8
500.0000	.555	-40.5	1.398	-174.0	.005	88.8	.968	-17.3
600.0000	.528	-44.8	1.513	-174.9	.005	95.2	.968	-20.4
700.0000	.517	-49.9	1.691	-176.2	.007	67.5	.971	-23.1
800.0000	.525	-54.4	1.815	-178.2	.007	72.4	.972	-25.8
900.0000	.545	-58.9	2.008	179.5	.006	84.5	.960	-29.3
1000.0000	.571	-62.8	2.189	175.7	.009	78.3	.936	-32.8
1100.0000	.580	-67.3	2.399	171.2	.007	60.0	.926	-36.3
1200.0000	.588	-71.3	2.560	165.9	.007	89.5	.933	-39.5
1300.0000	.571	-76.4	2.736	157.5	.008	67.2	.941	-42.0
1400.0000	.563	-82.3	2.865	151.3	.008	79.6	.930	-45.0
1500.0000	.553	-88.8	2.946	143.3	.006	79.9	.906	-48.1
1600.0000	.552	-95.2	3.077	137.0	.006	91.4	.895	-51.5
1700.0000	.551	-101.5	3.083	130.1	.009	102.3	.888	-54.8
1800.0000	.550	-107.5	3.174	123.9	.009	100.5	.884	-57.3
1900.0000	.536	-113.3	3.164	117.4	.006	109.5	.885	-60.2
2000.0000	.517	-119.8	3.193	110.7	.009	115.9	.881	-63.4
2100.0000	.495	-127.1	3.149	104.4	.010	124.2	.870	-66.6
2200.0000	.484	-135.3	3.143	97.3	.011	122.4	.867	-69.8
2300.0000	.484	-142.6	3.135	90.5	.012	131.7	.866	-72.3
2400.0000	.490	-148.5	3.120	83.5	.015	138.1	.868	-75.5
2500.0000	.499	-152.5	3.053	78.4	.016	136.3	.866	-78.7
2600.0000	.499	-155.8	2.991	71.4	.018	142.9	.864	-82.5
2700.0000	.485	-157.4	2.958	68.0	.018	143.9	.858	-86.6
2800.0000	.464	-160.6	2.810	62.9	.021	142.5	.852	-89.7
2900.0000	.439	-164.1	2.866	57.5	.022	149.3	.872	-93.4
3000.0000	.416	-168.6	2.713	54.5	.025	148.4	.864	-96.6
3100.0000	.403	-173.6	2.635	48.0	.030	143.6	.867	-101.0

– μ PC8152TB –



- μ PC8152TB -

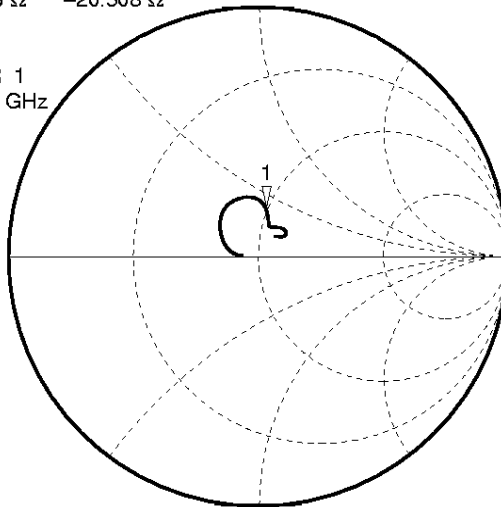
1.0 GHz output port matching

S-parameter (monitored at connector on board)

$T_A = +25^\circ\text{C}$, $V_{CC} = V_{out} = 3.0\text{ V}$

S₁₁
 REF 1.0 Units
 1 200.0 mUnits/
 ▽ 51.59 Ω -20.508 Ω

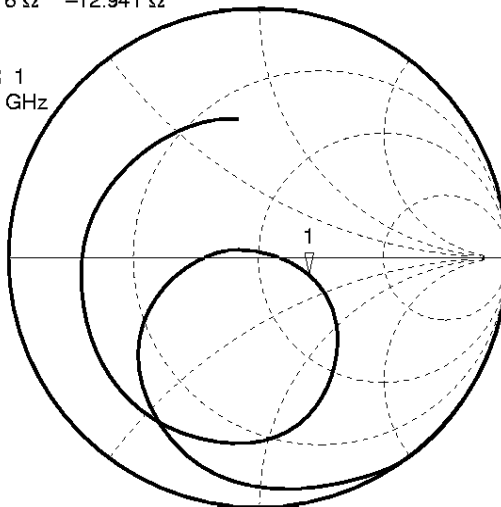
MARKER 1
 1.0 GHz



START 0.100000000 GHz
 STOP 3.100000000 GHz

S₂₂
 REF 1.0 Units
 1 200.0 mUnits/
 ▽ 75.816 Ω -12.941 Ω

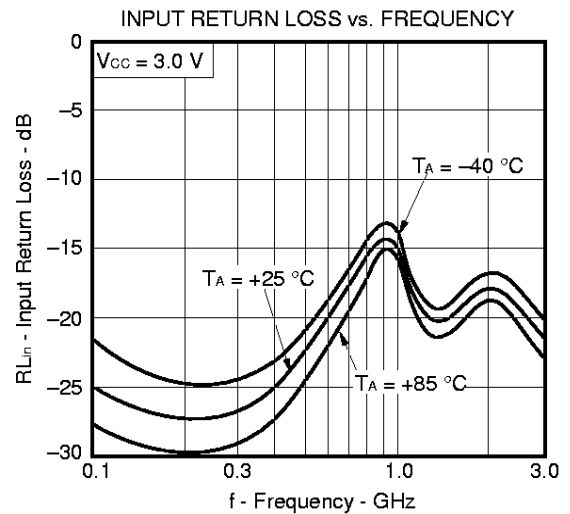
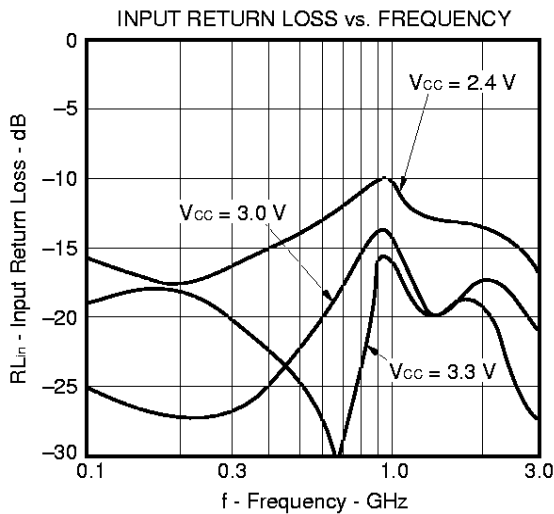
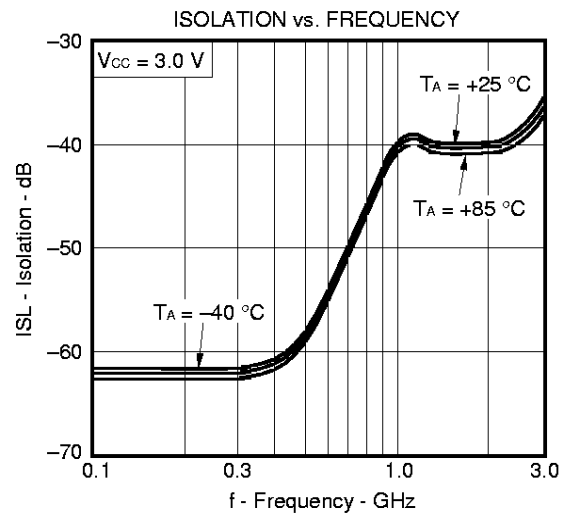
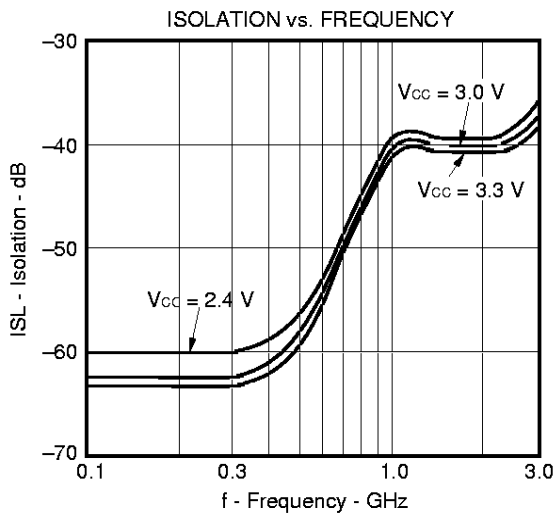
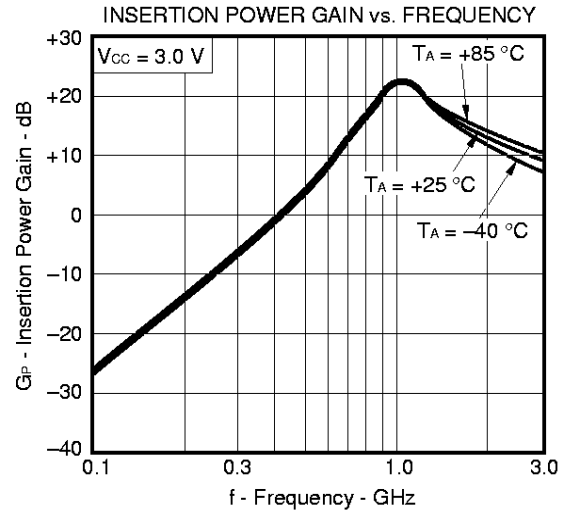
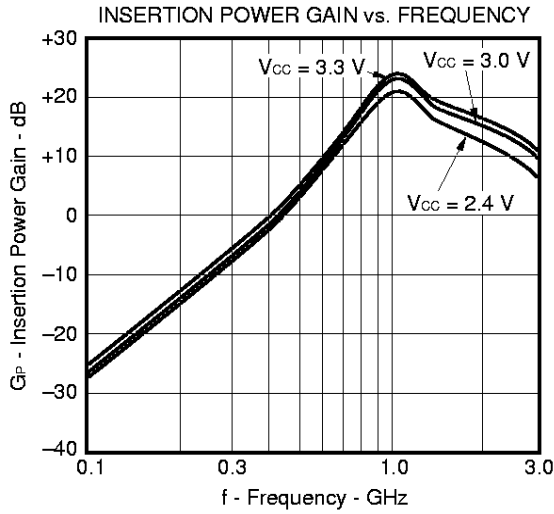
MARKER 1
 1.0 GHz



START 0.100000000 GHz
 STOP 3.100000000 GHz

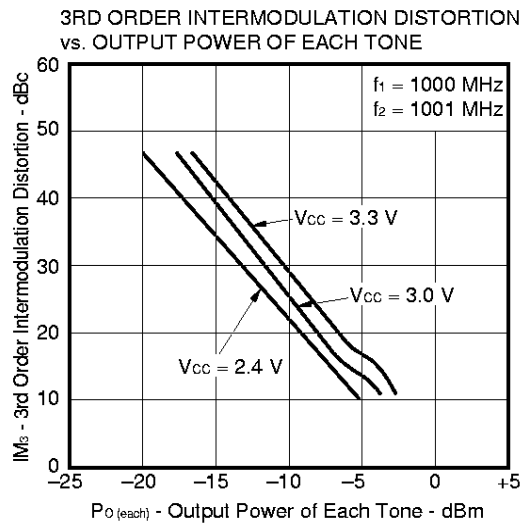
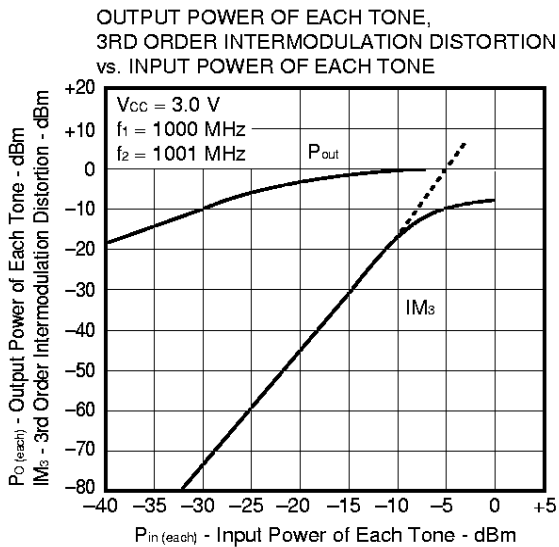
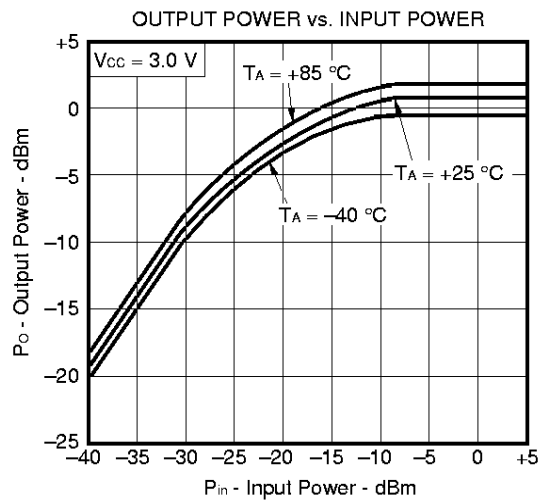
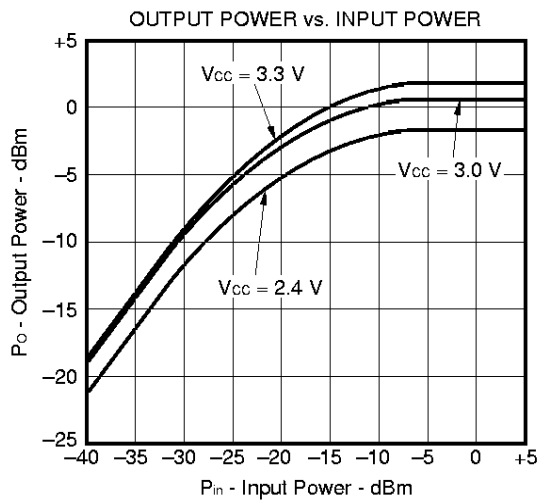
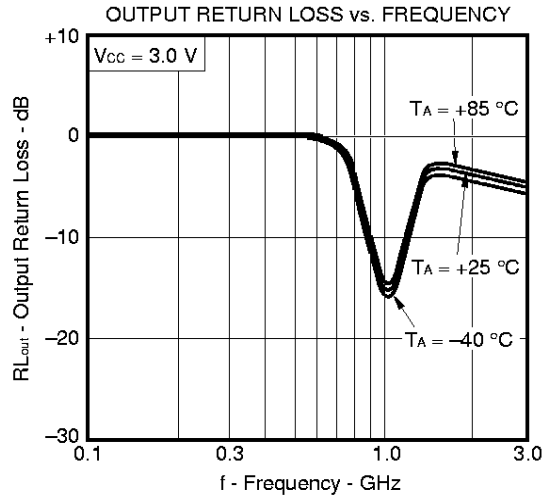
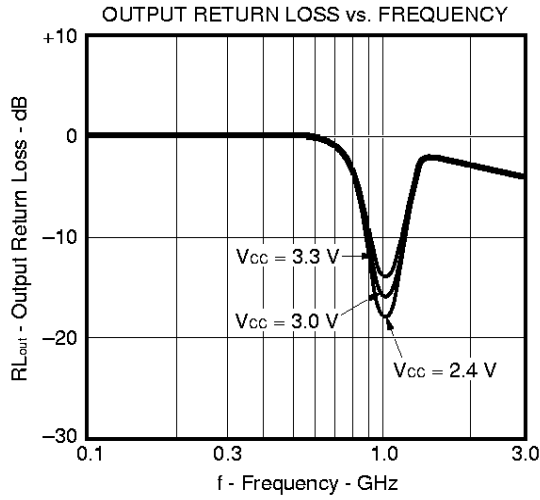
- μ PC8152TB -

1.0 GHz output port matching



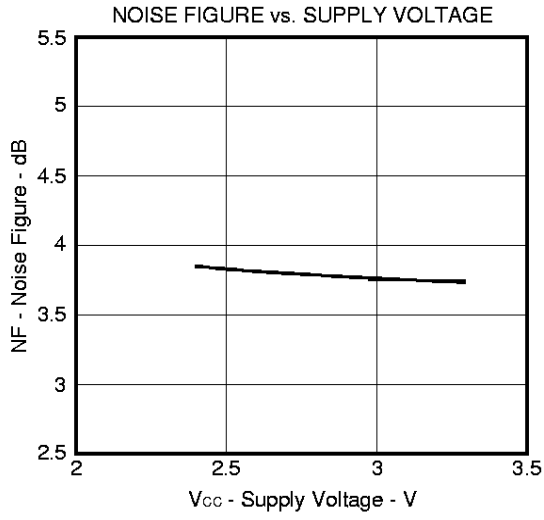
- μ PC8152TB -

1.0 GHz output port matching



– μ PC8152TB –

1.0 GHz output port matching



– μ PC8152TB –

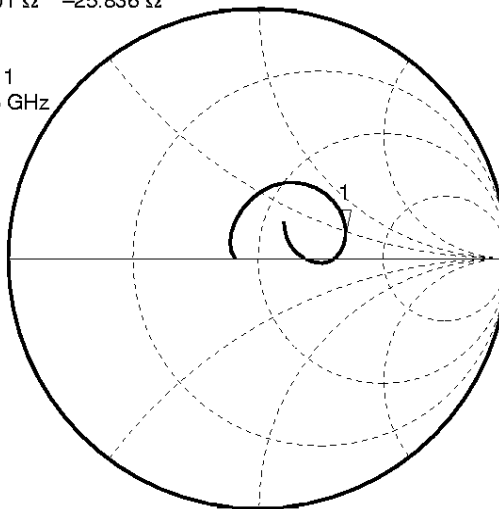
1.66 GHz output port matching

S-parameter (monitored at connector on board)

$T_A = +25^\circ\text{C}$, $V_C = V_{out} = 3.0\text{ V}$

S₁₁
 REF 1.0 Units
 1 200.0 mUnits/
 ▽ 98.301 Ω -25.836 Ω

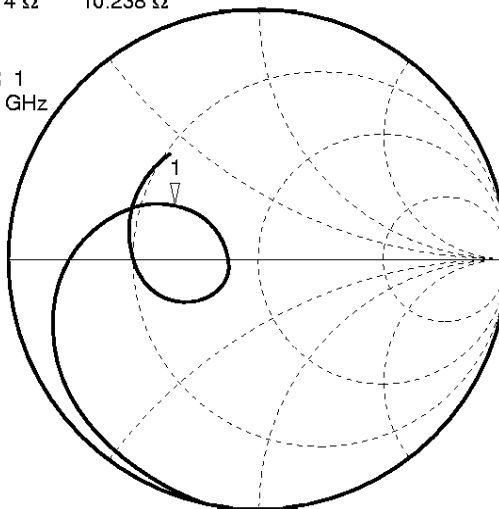
MARKER 1
 1.66 GHz



START 0.10000000 GHz
 STOP 3.10000000 GHz

S₂₂
 REF 1.0 Units
 1 200.0 mUnits/
 ▽ 22.714 Ω 10.238 Ω

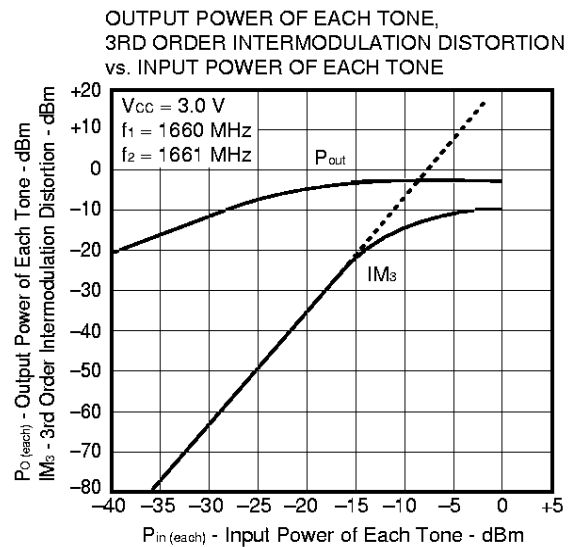
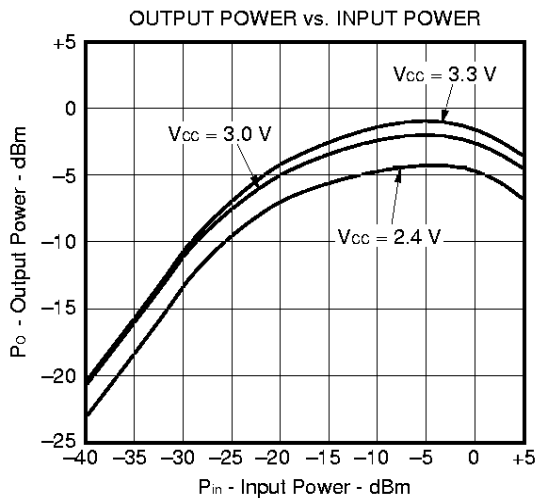
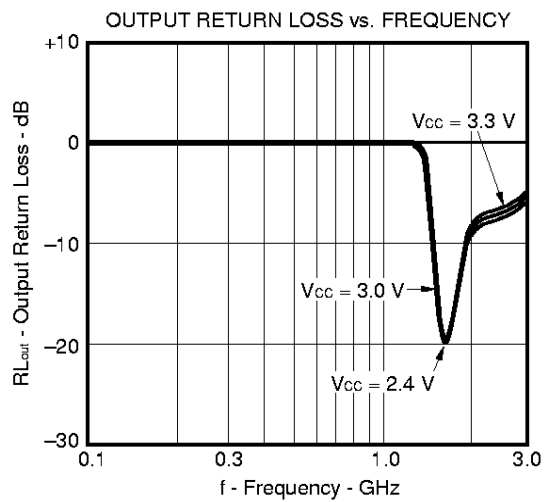
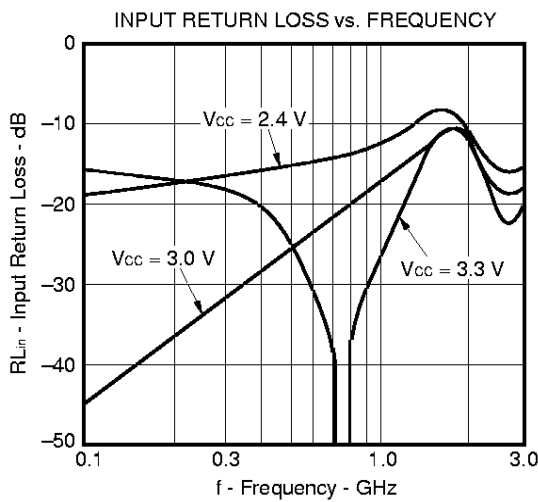
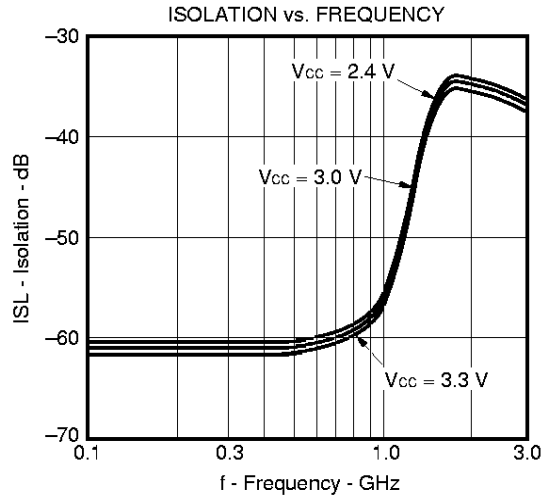
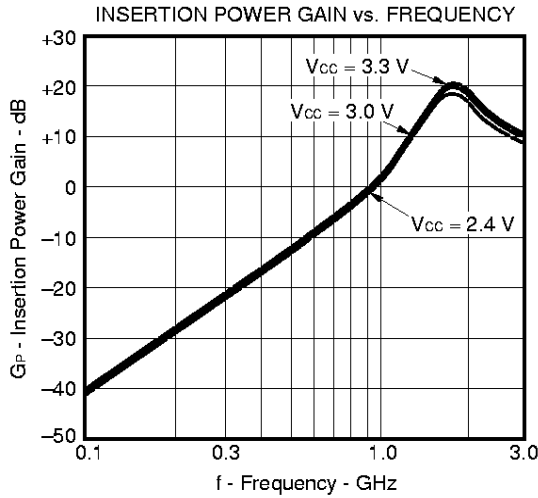
MARKER 1
 1.66 GHz



START 0.10000000 GHz
 STOP 3.10000000 GHz

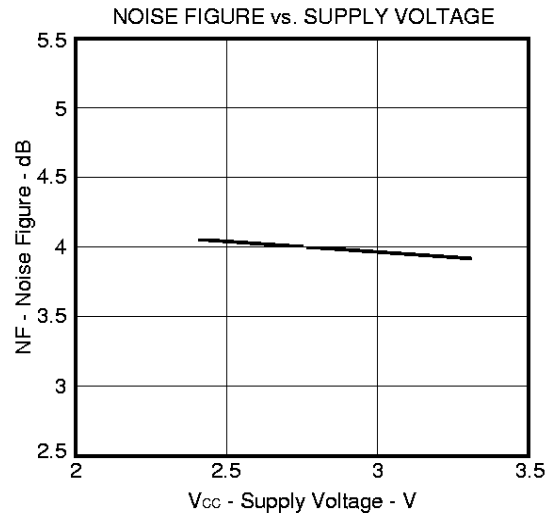
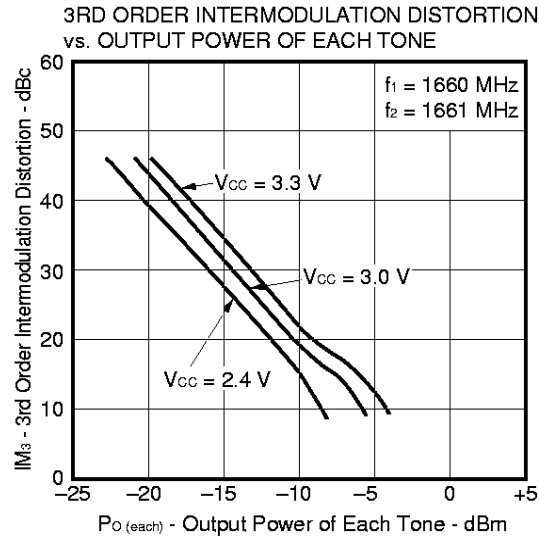
- μ PC8152TB -

1.66 GHz output port matching



– μ PC8152TB –

1.66 GHz output port matching



– μ PC8152TB –

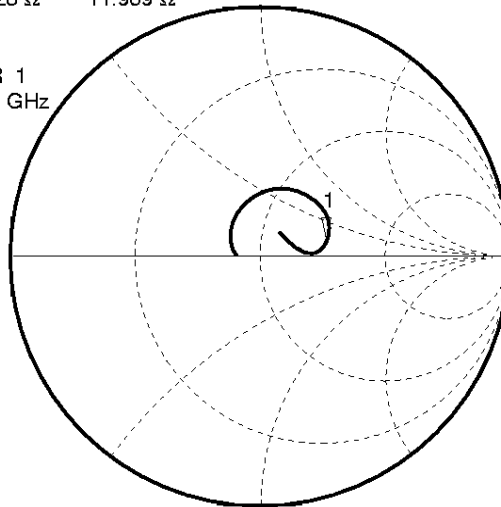
1.9 GHz output port matching

S-parameter (monitored at connector on board)

$T_A = +25^\circ\text{C}$, $V_{CC} = V_{out} = 3.0\text{ V}$

S₁₁
REF 1.0 Units
1 200.0 mUnits/
∇ 85.828 Ω 11.969 Ω

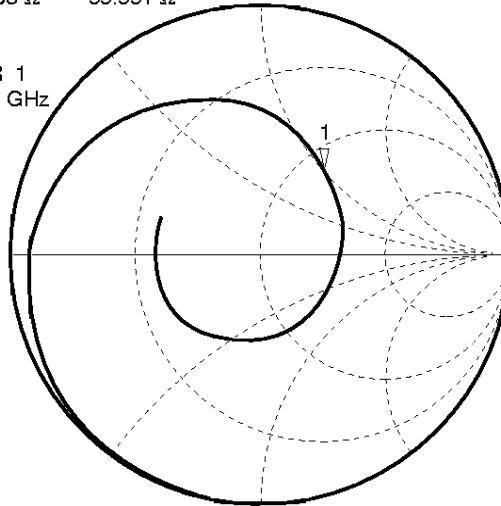
MARKER 1
1.9 GHz



START 0.100000000 GHz
STOP 3.100000000 GHz

S₂₂
REF 1.0 Units
1 200.0 mUnits/
∇ 62.398 Ω 55.551 Ω

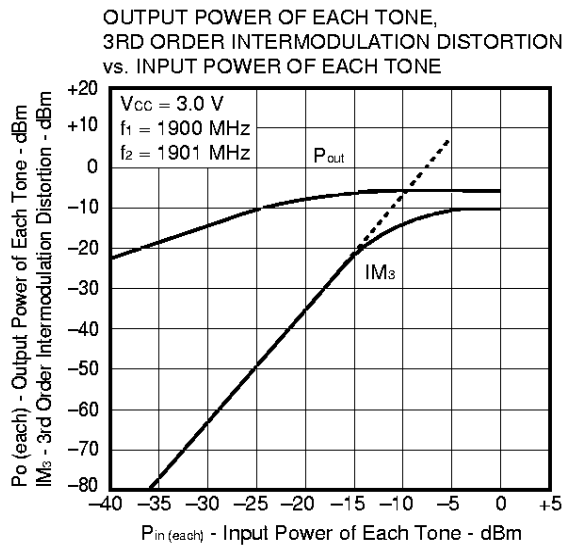
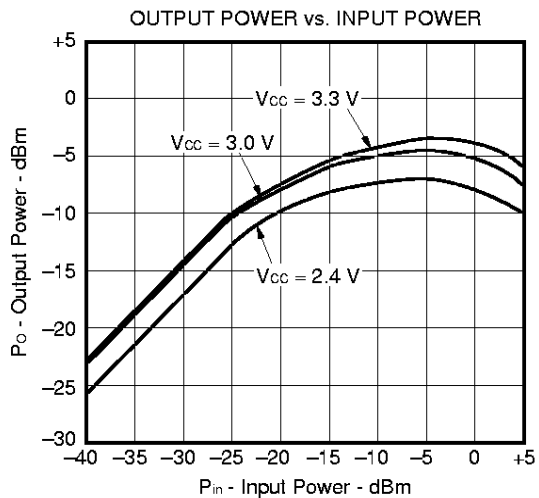
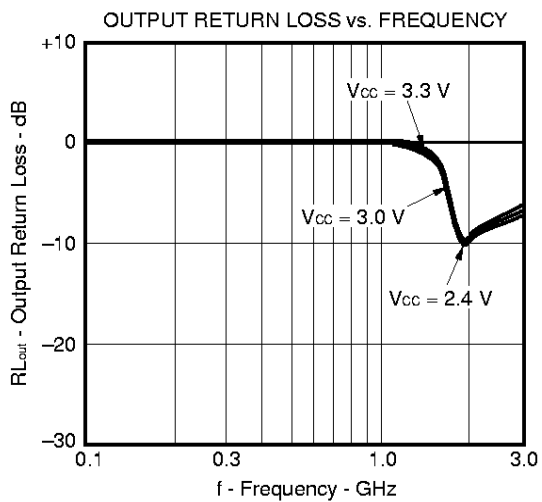
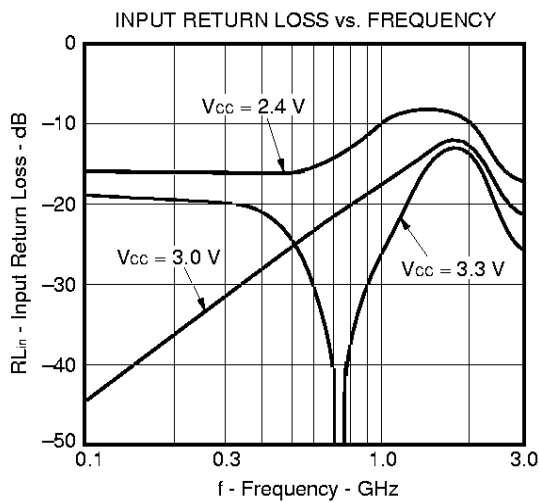
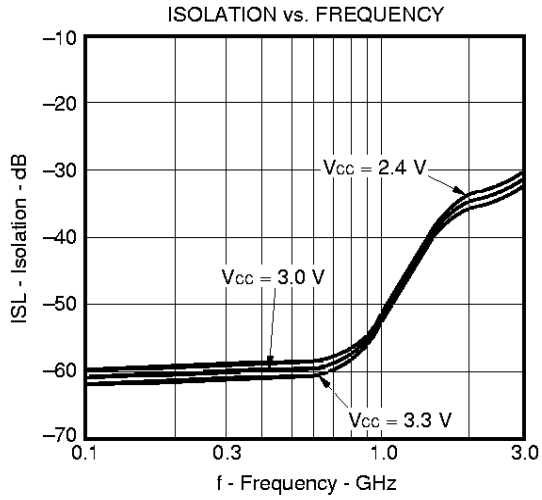
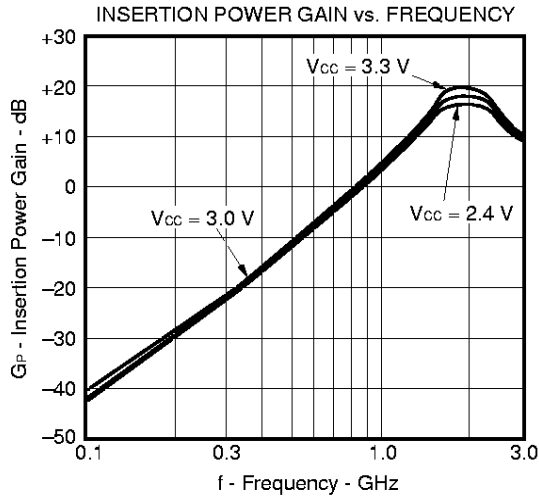
MARKER 1
1.9 GHz



START 0.100000000 GHz
STOP 3.100000000 GHz

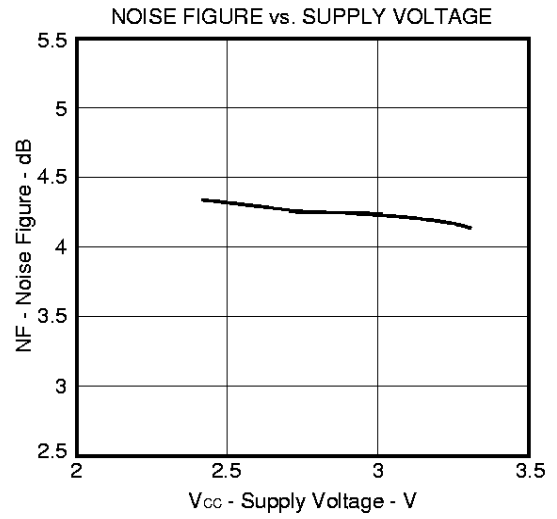
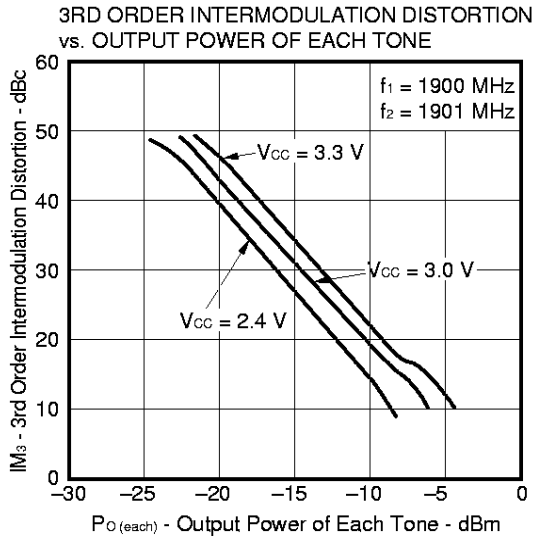
- μ PC8152TB -

1.9 GHz output port matching



- μ PC8152TB -

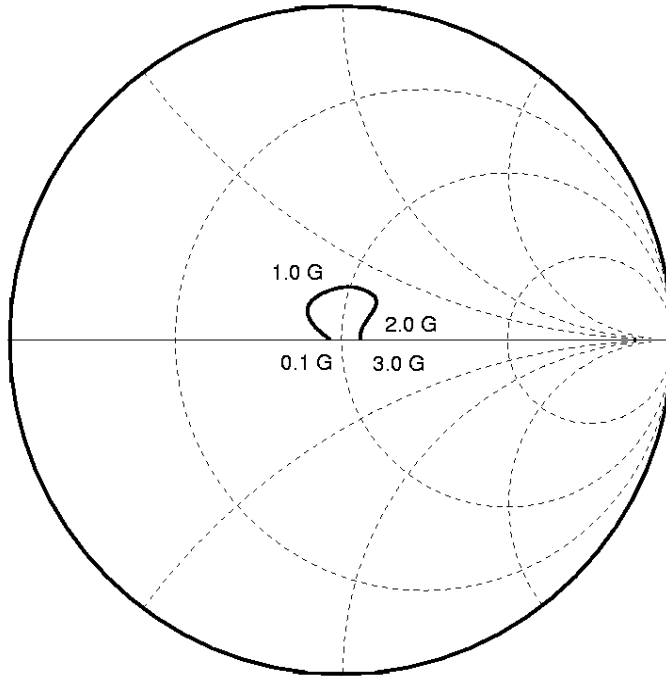
1.9 GHz output port matching



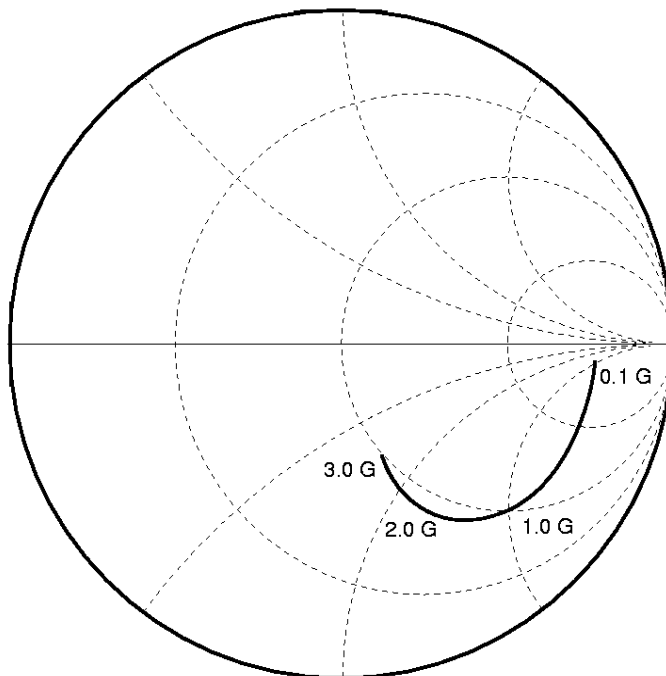
S-parameter ($V_{CC} = V_{out} = 3.0\text{ V}$)

– μ PC8152TB –

S_{11} –Frequency



S_{22} –Frequency



Typical S-parameter values (T_A = +25°C)

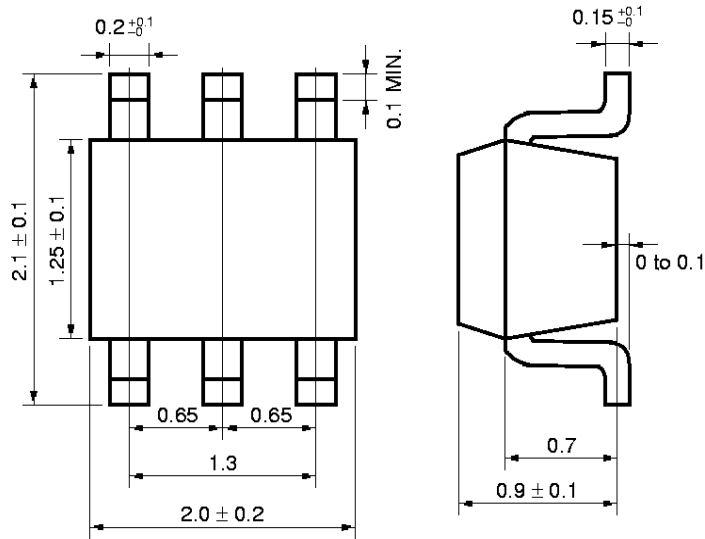
μPC8152TB

V_{CC} = V_{OUT} = 3.0 V, I_{CC} = 5.6 mA

FREQUENCY MHz	S ₁₁		S ₂₁		S ₁₂		S ₂₂	
	MAG	ANG	MAG	ANG	MAG	ANG	MAG	ANG
100.0000	.062	168.0	6.691	-0.3	.002	40.8	.775	-3.3
200.0000	.047	169.1	7.049	-3.7	.001	101.6	.773	-6.6
300.0000	.055	166.9	7.418	-9.3	.003	97.3	.761	-9.1
400.0000	.078	162.1	7.883	-16.0	.003	70.7	.759	-12.0
500.0000	.101	155.6	8.311	-22.1	.005	76.7	.754	-15.3
600.0000	.121	147.4	8.583	-29.7	.004	80.5	.754	-18.3
700.0000	.135	141.2	9.093	-37.3	.006	79.8	.756	-21.3
800.0000	.143	133.2	9.276	-45.4	.005	85.9	.755	-24.7
900.0000	.146	122.4	9.572	-53.6	.009	89.6	.752	-28.1
1000.0000	.146	108.9	9.763	-62.6	.009	70.3	.745	-32.0
1100.0000	.153	97.4	9.851	-71.9	.007	90.8	.733	-36.3
1200.0000	.157	82.7	9.926	-80.5	.011	84.9	.723	-40.3
1300.0000	.164	73.3	9.816	-91.2	.010	81.9	.710	-44.3
1400.0000	.168	63.4	9.586	-99.6	.011	81.4	.679	-48.5
1500.0000	.171	56.1	9.332	-109.4	.011	82.3	.649	-52.0
1600.0000	.165	47.2	9.128	-117.9	.009	79.0	.624	-56.3
1700.0000	.164	38.7	8.544	-126.1	.011	77.5	.591	-59.2
1800.0000	.156	30.2	8.152	-133.5	.011	76.8	.557	-61.4
1900.0000	.158	25.1	7.607	-140.6	.011	75.9	.527	-63.4
2000.0000	.148	21.5	7.264	-147.5	.012	75.8	.498	-65.6
2100.0000	.140	19.1	6.759	-153.7	.013	82.6	.476	-66.8
2200.0000	.124	21.6	6.366	-159.7	.012	92.4	.455	-67.1
2300.0000	.104	19.3	6.028	-165.7	.014	88.9	.438	-68.1
2400.0000	.085	17.8	5.642	-171.5	.015	89.8	.418	-68.1
2500.0000	.068	10.9	5.200	-176.0	.015	87.2	.399	-69.5
2600.0000	.059	9.9	4.874	179.1	.016	94.2	.390	-69.2
2700.0000	.055	-0.1	4.527	175.9	.017	93.5	.380	-70.2
2800.0000	.054	0.2	4.202	171.3	.022	88.2	.372	-70.3
2900.0000	.054	1.9	4.005	167.7	.021	91.4	.369	-69.5
3000.0000	.055	12.0	3.697	164.4	.021	86.8	.360	-69.6
3100.0000	.057	22.3	3.502	160.4	.023	83.9	.352	-71.0

PACKAGE DIMENSIONS (Unit: mm)

6 pin super minimold



NOTES ON CORRECT USE

- (1) Observe precautions for handling because of electro-static sensitive devices.
- (2) Form a ground pattern as wide as possible to minimize ground impedance (to prevent undesired oscillation).
All the ground pins must be connected together with wide ground pattern to decrease impedance difference.
- (3) The bypass capacitor should be attached to Vcc line.
- (4) The inductor (L) should be attached between output and Vcc pins. The L and series capacitor (C2) values should be adjusted for applied frequency to match impedance to next stage.
- (5) The DC capacitor must be attached to input pin.

RECOMMENDED SOLDERING CONDITIONS

This product should be soldered in the following recommended conditions. Other soldering methods and conditions than the recommended conditions are to be consulted with our sales representatives.

μ PC8128TB, μ PC8151TB, μ PC8152TB

Soldering method	Soldering conditions	Recommended condition symbol
Infrared ray reflow	Package peak temperature: 235 °C Hour: within 30 s. (more than 210 °C) Time: 3 times, Limited days: no. ^{Note}	IR35-00-3
VPS	Package peak temperature: 215 °C Hour: within 40 s. (more than 200 °C) Time: 3 times, Limited days: no. ^{Note}	VP15-00-3
Wave soldering	Soldering tub temperature: less than 260 °C, Hour: within 10 s. Time: 1 time, Limited days: no. ^{Note}	WS60-00-1
Pin part heating	Pin area temperature: 300 °C, Hour: within 3 s/pin. Limited days: no. ^{Note}	

Note It is the storage days after opening a dry pack, the storage conditions are 25 °C, less than 65 % RH.

Caution The combined use of soldering method is to be avoided (However, except the pin area heating method).

For details of recommended soldering conditions for surface mounting, refer to information document **SEMICONDUCTOR DEVICE MOUNTING TECHNOLOGY MANUAL (C10535E)**.



ATTENTION

OBSERVE PRECAUTIONS
FOR HANDLING
ELECTROSTATIC
SENSITIVE
DEVICES

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Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

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Anti-radioactive design is not implemented in this product.